Sujal N. Patel (+9+21-1-36-1-30). 09574234622

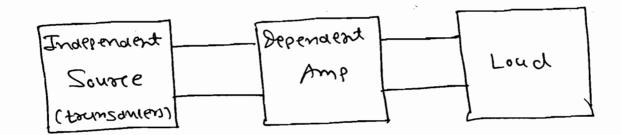
ECE

ACE Academy

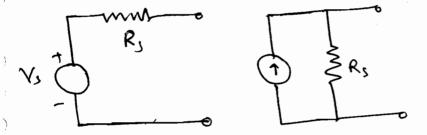
Batch: PM 1(B)

Analog Citcults.

į . i. . *(* ... •



micou phone



Voitage amp Vo= KVin [VCVS].

Current amp To= KIIn [cccs].

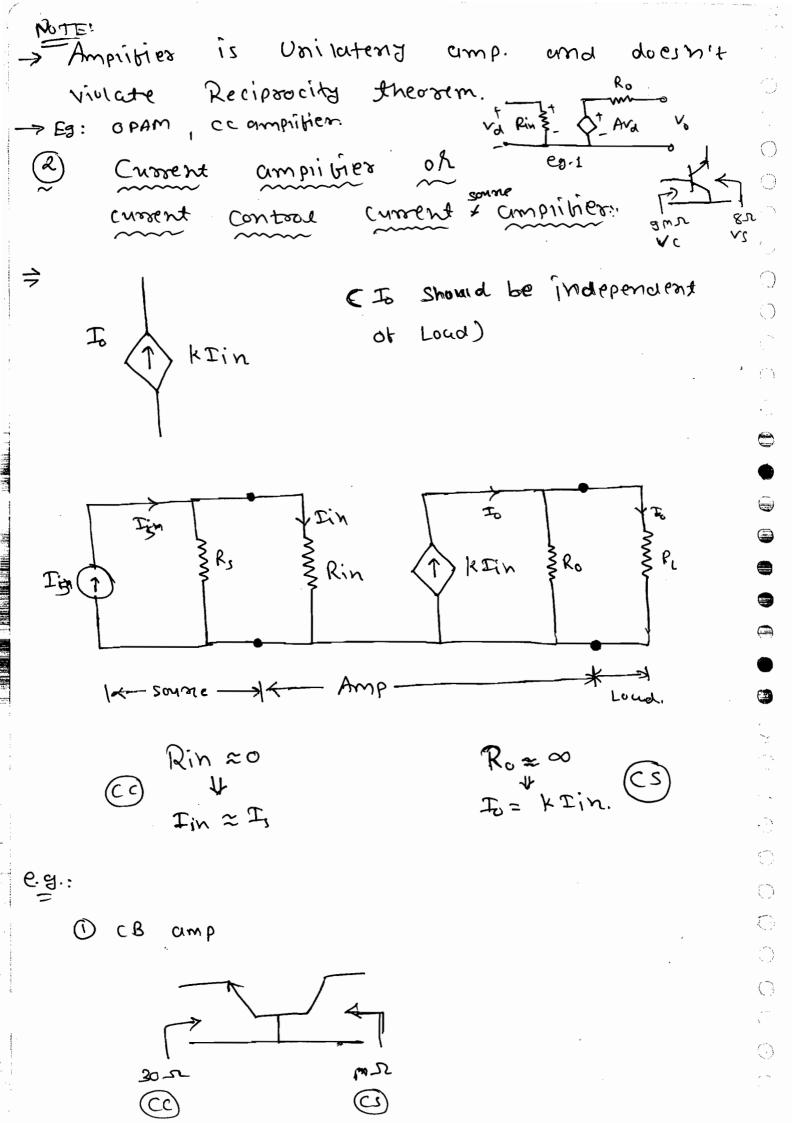
Transconduction amp Io= KXIN [VCCS]. Truns Resistand amp Vo= K I'm [ccVs].

Four Types Ob Amplifier:

Voltuge ampilières of (1)Voltage contral voltage Sonre.

Vo=kin (Vo should be inde. of RL). → \C\Z kYin *₹*−bνο*1*→*ξ*−−− SOURCE AMP

Rin= 00, Ru= 0. (Ideal). Yor KYIN VinzVs



Characterstics of tusseus sourc: 5 I BIT e.g. @ \Rightarrow R. = $\frac{1}{5100} = \frac{1}{0} = \infty$. current Source. Soi BJT is Source troborn) (ontout Voitage Jours Conducturice Amp. (oh) 9 vin klin Douns conductunce. In = gmvin. Rin R, کچ لار - Amp K- Source - + $R_o \approx \infty$. Rin ~ 0 \Rightarrow 1 ₩ In = gmvin Vin = Vi current source. voltuge contru

()

()

(

(:

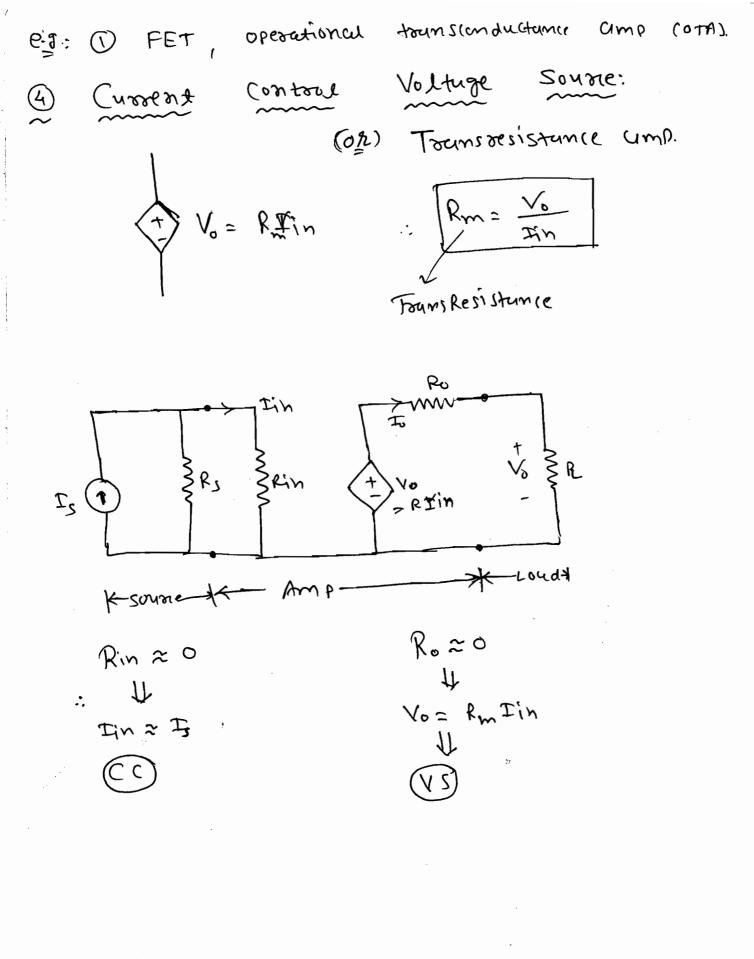
()

(1)

()

()

()



 \bigcirc

 \odot

 \bigcirc

()

()

()

0

٧

 \bigcirc

 \bigcirc

 (\cdot)

 \bigcirc

(

()

 \bigcirc

()

(:)

()

Amp Rin Ro

1) Voltage high Low Ar= Voltage

e) Current Low high AI = Io (csce).

3) Towns (orductance high High Um = Io (CSVC).

W) Towns Resistance Low Low Rm= VO (VSCC).

Fx-1 Find Voltage gain, current gain and power gain of the current ampilier.

 $T_0 = \frac{100}{110} \times 100 \text{ M} \text{ Fin.}$

 $\therefore \frac{T_0}{T_{in}} = 4 \text{ Age } A_T = \frac{100 \times 100}{110}.$

: AAR 160 14

: Now, Yo= To xlok.

Vo = 100 x 100 x 10K x Iin.

: Vo= 108 x Iin.

$$I_s = \frac{1k}{11k} \times \Sigma in.$$

$$T_0 = \frac{100 \times 100}{110} \times \frac{100}{11} T_3.$$

$$\therefore \boxed{\frac{T_o}{T_s} = \frac{10^{S}}{100 \times 11}} = A_T.$$

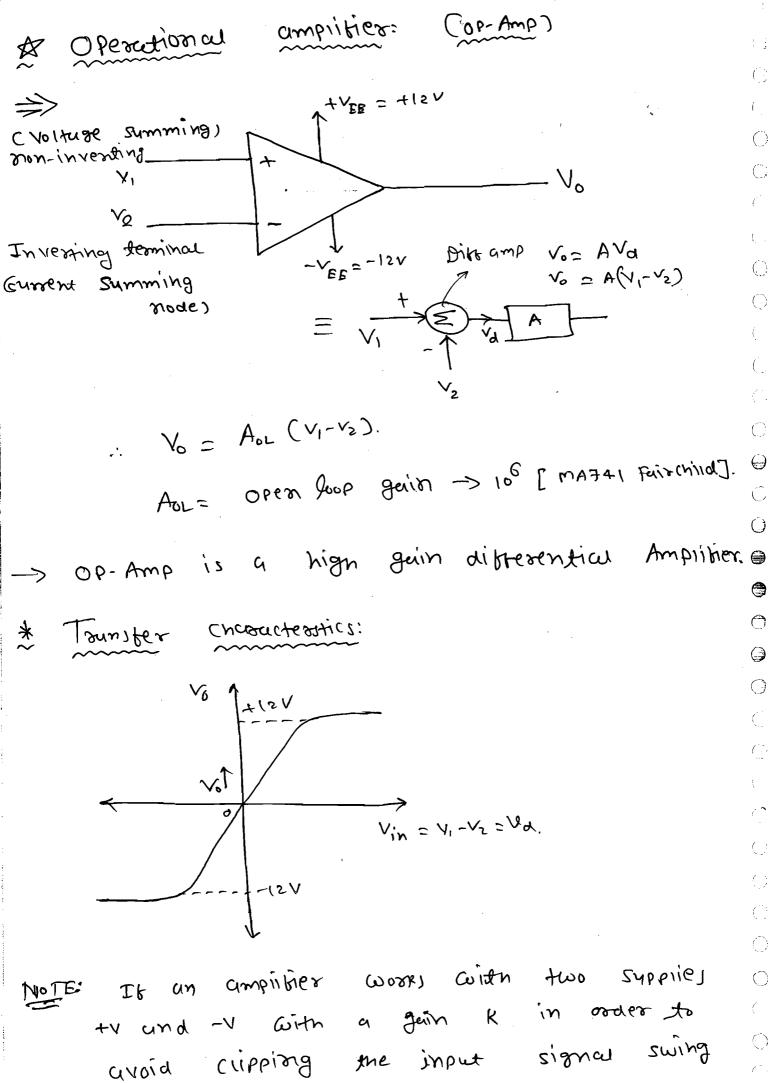
()

 Θ

$$V_{S} = \frac{10 \times 10^{3}}{10 \times 10^{3}} \times \frac{10^{8}}{10^{8}} . V_{0}$$

$$\therefore \quad \boxed{\frac{V_0}{V_2} = A_{\gamma} = \frac{10^{4}}{11\times110}}.$$

Find I of the fig. It Characterstic) is 9 Ex-1 given. R= 0.2 = 200.1. : SIOP = I(v = 1/200. 0.10. (0.5,0) to (0.7,1m). y-4 = x-4 $\frac{T-0}{100} = \frac{V-0.5}{0.2}$: 200 T + 0.5 = V. LVY & 7 8/28. in It is 1 k 1 200 x T 0.5V 501 I (201) K : I = 3.75 . MA V= 200 x 3.35 x103 +0.5 .. N= 7.5 +0.5 = 0.8 V. =) V=0-8V



()

()

0

 \bigcirc

 $\hat{\mathbb{C}}$

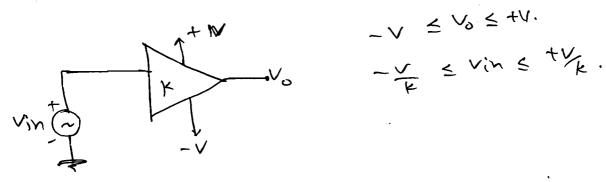
0

0

0

 \bigcirc

()



* Three Basic Modes ab operation ob an

(1) Negative teedback:

Linear

VCVS

CCCS

Amp

Peak Detector

CCVS

Cipper

Cripper

Crompper

Subtracter

Instrumentation

Amp

Exp comp.

Open loop Brased Positive

feedbuck

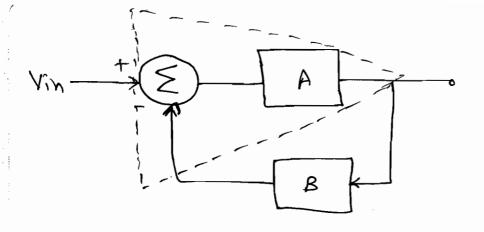
Comproctors (Detectors) schmit sigger

-> multivibacters.

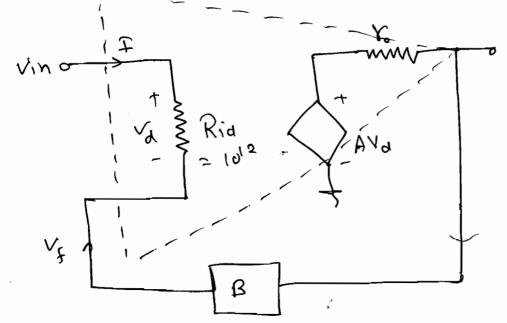
=> In order to Soive cidents involving -ve feedback two seasistic assumstions are mude.

Vnoniversing = Vinversing

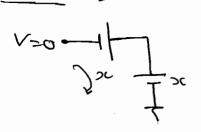
Op-cump docuous no current.



-> OP-Amp is YCVS.



OP-AMP is mulcotos.



T R T X

 \bigcirc

 \bigcirc

4

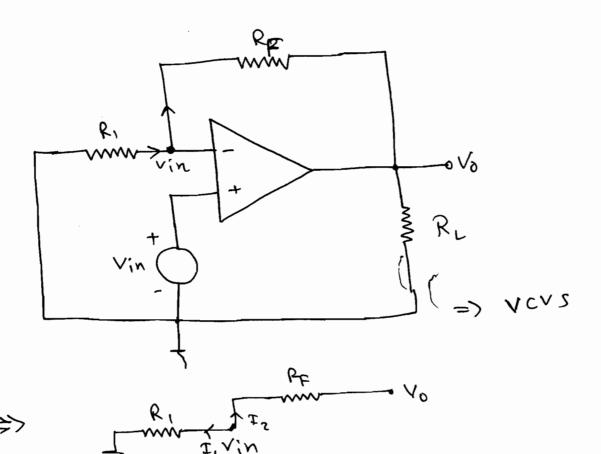
50, Y=0 & I=0.

(1) Voitage Ampilier (or) Non-Inverting

Amplifier (OA) Voltage Control Voltage

Source Amplibier).

*

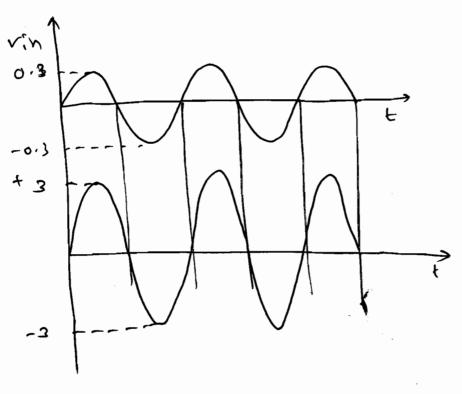


 $V_0 = \left(1 + \frac{R_F}{R_I}\right) Vin$

Vin= 0.3 sint, 1= 9x, R=1K.

Vo=(1+ =) Vin

You loving 3 gint.



(2) Inverting Amplifier (on) Current Control
Voltage Source (on) Trans Resistance Amplifier.

3)

(:`.)

()

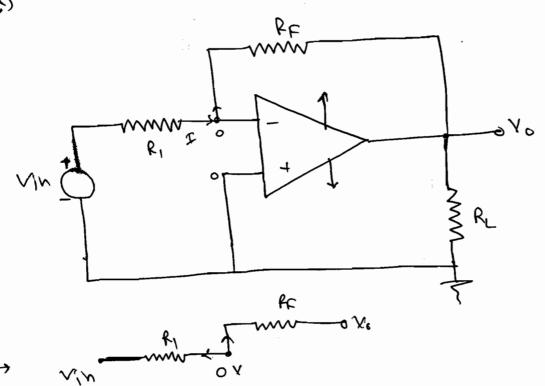
()

()

Ō

0

(

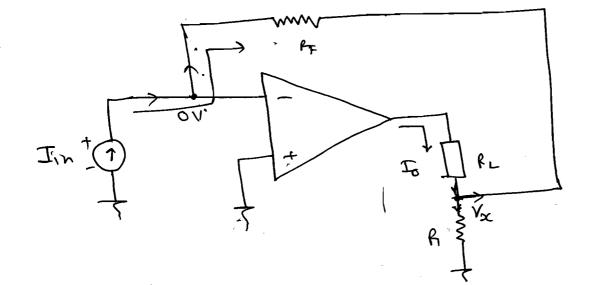


KCL 0-Vin + 0-Vo = 0

$$\rightarrow$$
 $V_0 = (-R_F) \left(\frac{V_{in}}{R_i}\right)^2$ cursent contout.

: Vo=- RE I'M.

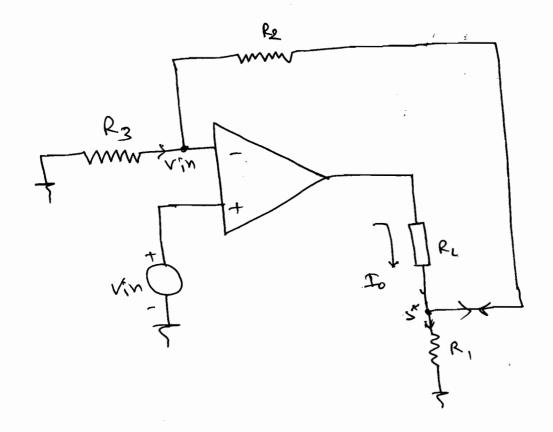
: Tours Resistance Rm2 Vo



KCL:
$$I_0 = \frac{Vx}{R} + \frac{Vx^{-0}}{R}$$

Sub @ in 0

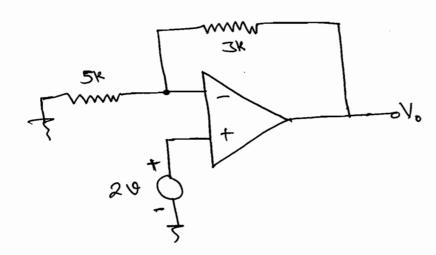
Ampriber (OR) Voituge Tours Conductance (4) Source. Wood + Current Control



$$I_{x} = \frac{R_1}{R_1 + R_2 + R_3} I_0.$$

: fours conductum(e)
$$g_m = \frac{R_1 + R_2 + R_3}{R_1 R_3}$$

Ex-1 Find the OIP Voltage it OP-AMP is 17 Consider ideal.



$$V_0 = \left(1 + \frac{R_F}{R_I}\right) V_i N.$$

0

$$V_0 = (1 + \frac{3}{5}) 20$$

$$\mathbb{R}_{1} = 1 \times \mathbb{R}_{1} = 2 \times \mathbb{R}_{2} \times \mathbb{R}_{3} \times \mathbb$$

$$= \frac{\sqrt{0}}{3} - \frac{25232}{34} - \frac{\sqrt{0}}{3}$$

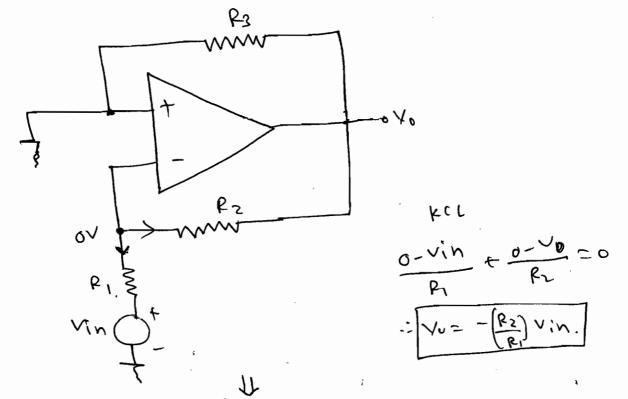
·: 76 = 38 4 14.

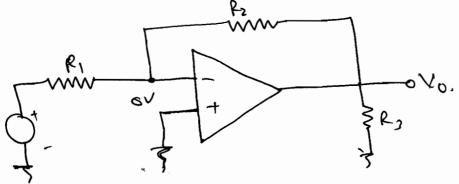
$$T_0 = \frac{V_0}{3\kappa} + \frac{V_0}{2\kappa}$$

$$= \frac{5V_0}{6\kappa}$$

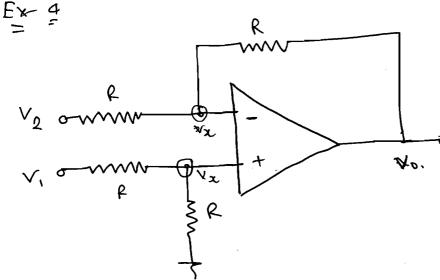
$$= \frac{5(-4\sin t)}{36\kappa}$$

$$T_0 = -\frac{10}{3} \sinh t mA$$





$$. \quad \forall_0 = -\left(\frac{\rho_2}{\rho_1}\right) \vee_{i} \gamma_i,$$



$$V_2$$
 V_2
 V_2
 V_2
 V_3
 V_4
 V_5
 V_6

$$\therefore V_{x} = \frac{R}{R+R} \cdot V_{1}$$

$$: V_{0,1} = \left(1 + \frac{g}{g}\right) \frac{V_1}{2}$$

Subtoucton.

Ex ? ΙK 3¥ 104. lox イタニ 4-Vo = - 10 200=-4 No=- 2 10 Ex- & Find Vp, Vn& Vo. 40 Ļ 24 3×. : VN= Up = \$ xVo. .,

 \bigcirc

 \bigcirc

 $(\dot{})$

 $(\dot{\ })$

 \bigcirc

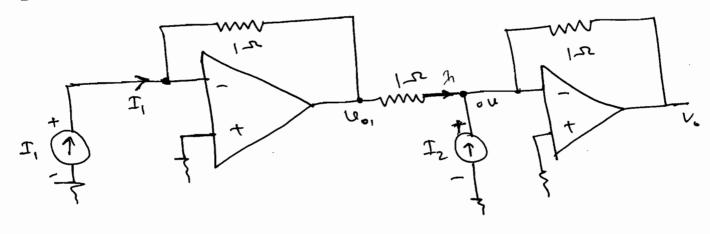
 \bigcirc

(<u>;</u>)

0

 \subset

(_



$$\therefore V_{01} = -1(T_{1})$$

$$V_{01} = -T_{1}$$

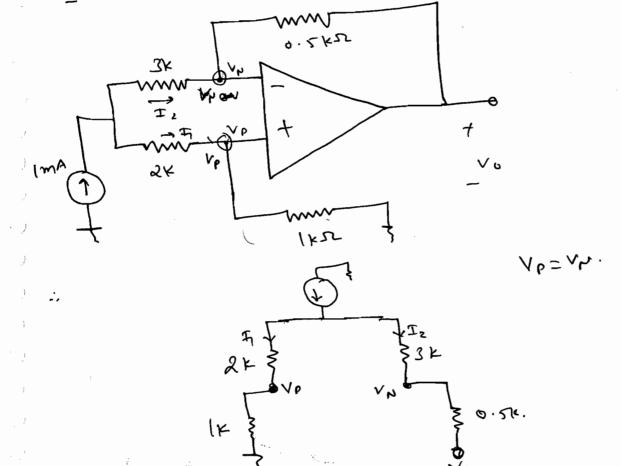
$$\frac{V_{01}-0}{1} + \overline{I_{2}} = \frac{0-V_{0}}{1}$$

$$-\overline{I_{1}} + \overline{I_{2}} = -V_{0}$$

$$\frac{1}{1} + \overline{I_{2}} = -V_{0}$$

$$\frac{1}{1} + \overline{I_{2}} = -V_{0}$$

EX-8



$$T_{1} = \frac{1m(3k)}{2k+3k} = 0.6mA$$

$$T_{2} = T - F$$

$$T_{2} = 0.4mA$$

$$V_{0} = T_{1} \times 1k$$

$$V_{0} = 0.6V.$$

$$0.4m = \frac{0.6 - V_{0}}{0.5k}$$

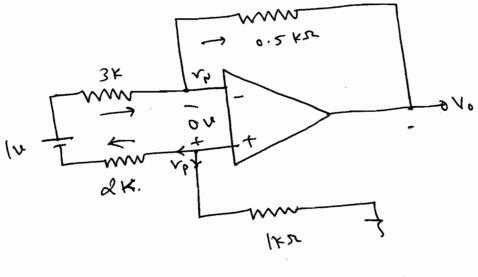
$$V_{0} = \frac{V_{0} - V_{0}}{0.5k$$

()

 \bigcirc

04 I(0.2k) 4/0 4I(1k) =0

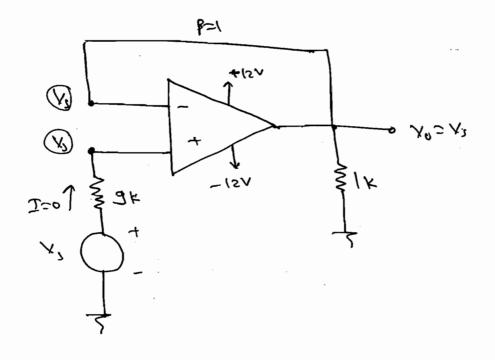
Vo= -1.50



Vp=

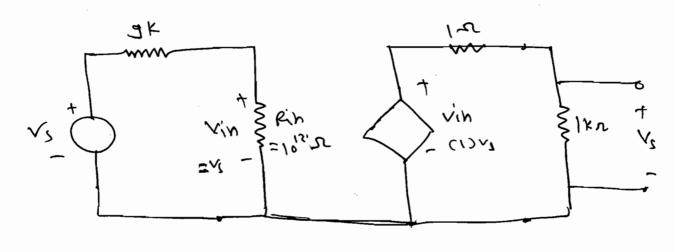
* Butter (or) voitage tollower (or) Onity gain amplifier.

→ Impedence motiting device is device consich connect high impedence Source to Low impedence Loud.



$$A_{S} = \frac{A}{1+AB} = \frac{10^{6}}{1+10^{6}} = 1.$$

$$A_5=1.$$



the Impedence

(<u>)</u>

(()

(

(

ି *ଭ*

0

⊕ ⊘

 \bigcirc

(

(

· ·

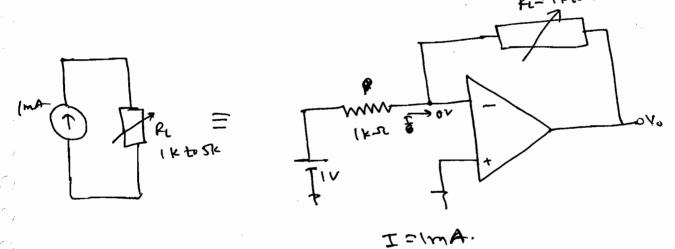
(

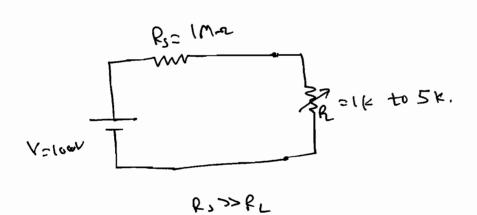
(

(

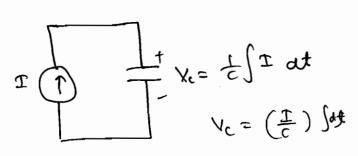


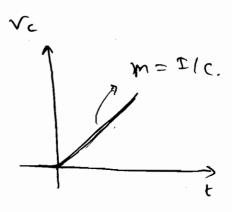
*





*

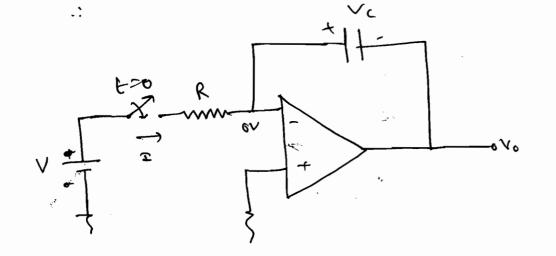




$$V_{c} = \left(\frac{\pm}{c}\right) t$$

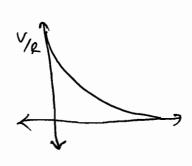
$$\Rightarrow y = V_{c}$$

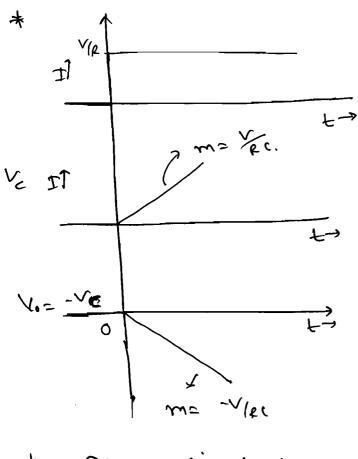
$$\Rightarrow x = t$$



$$V_{c} = \frac{1}{c} \int \mathbf{T} dt = \left(\frac{\mathbf{T}}{c}\right)^{\frac{1}{2}} = \left(\frac{\mathbf{V}}{\mathbf{R}c}\right)^{\frac{1}{2}}.$$

$$\begin{array}{c|c}
V_{c} & T = \frac{S - V_{c}}{I} \\
\hline
0V & SA \\
IV & 4A \\
3V & 2A \\
SV & 0A
\end{array}$$





* Ditterentiator:

 \Rightarrow

 $\frac{\sqrt{o} = \frac{R_F}{R_I}}{\sqrt{s_0}} = \frac{-\frac{R_F}{R_I}}{(\frac{1}{2}s_0)} = -\frac{(R_C)s_0}{\sqrt{s_0}}$ $\sqrt{o} = \frac{-\frac{R_F}{R_I}}{(\frac{1}{2}s_0)} = -\frac{(R_C)s_0}{\sqrt{s_0}}$

```
: Vi= Voc+ Ymsinwt
  :. X:= 1+1 sin ATT +
     V; = 1+ Sin ATT +.
   Vi = 1+ sin 200TT7
  -: Yo= (- PC). di.
       = (-100 X(08) X (0) 200TT (200T)
         - 0.628 COSTODITE.
       4=0
    : Vo= -0.628.
          275K= 200 KX
           2 5 = 20d 00
            T= 10 ms.
Ex! Find the capacital voltage at t=0.5ms
   it Switched is closed at t=0. Asyme
  Capacitos initiand uncharged.
```

()

()

(·

 (\cdot)

 \bigcirc

 \ominus

 \bigcirc

(,

()

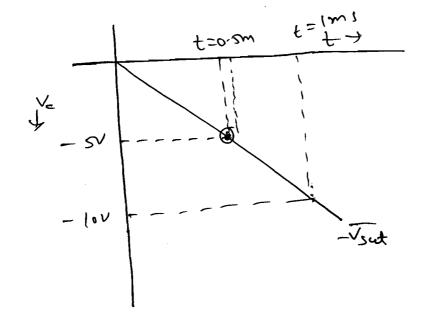
(

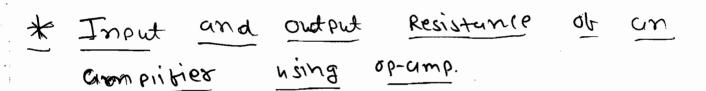
()

V-Yearoco

$$I = \frac{0-10}{1k}$$

$$= \frac{-10 \times 10^{-3}}{1 \times 10^{-6}} \times [\pm]_0$$





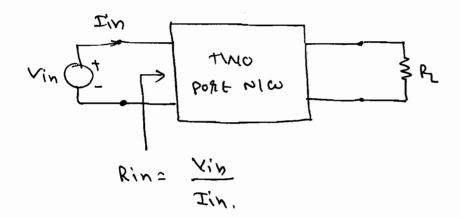
(<u>.</u>.)

0

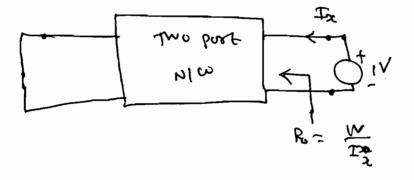
()

 \odot

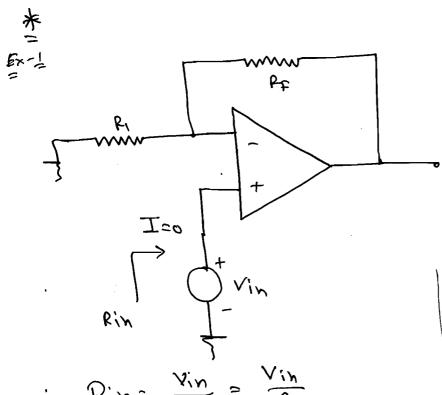
1 Input Resistance:



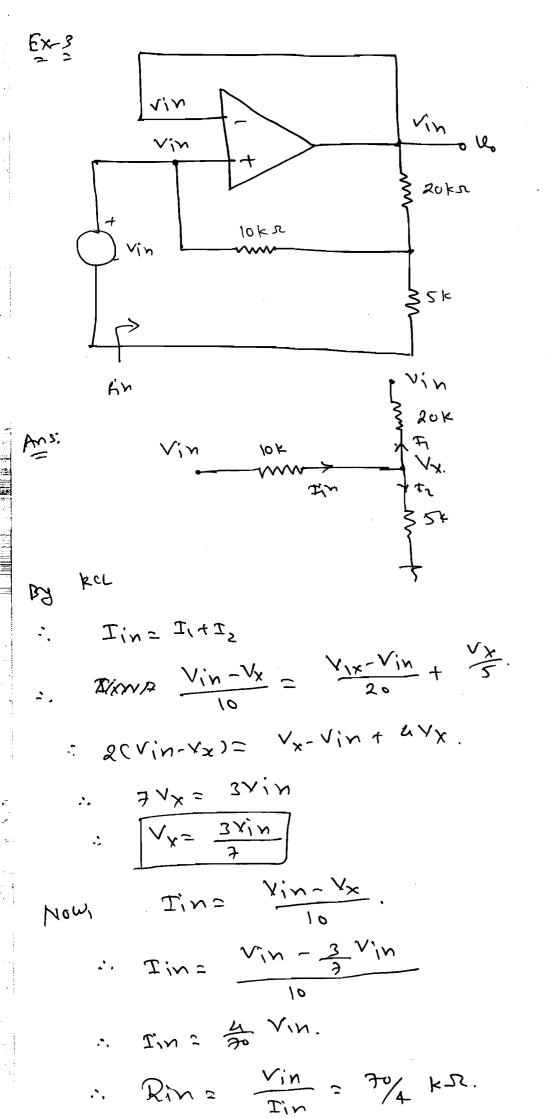
@ Output Resistance:



- 1 OC PL
- @ Sc Vin
- 3 Gamect 14 Source of 018 terminals



$$\therefore Rin = \frac{Vin}{Iin}$$

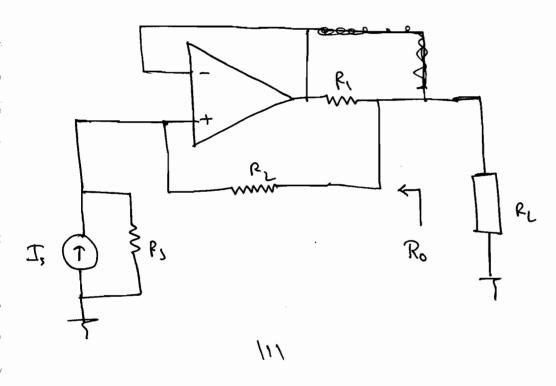


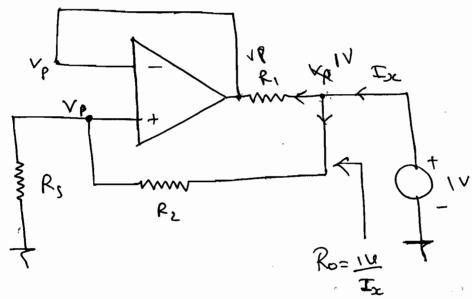
()

()

9

Ex-1 for Old Ro





$$V_{p} = \frac{R_{S}(1)}{R_{S}^{2}R_{2}} \Rightarrow 1-V_{p} = \frac{R_{2}}{R_{2}+R_{1}}$$

$$T_{x} = \frac{1 - V_{p}}{R_{1}} + \frac{1 - V_{p}}{R_{2}}.$$

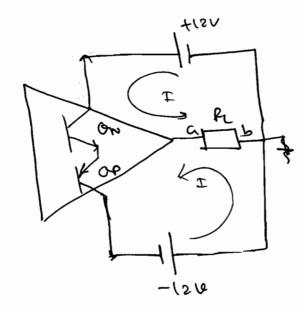
$$R_0 = \frac{1}{T_{2e}}$$

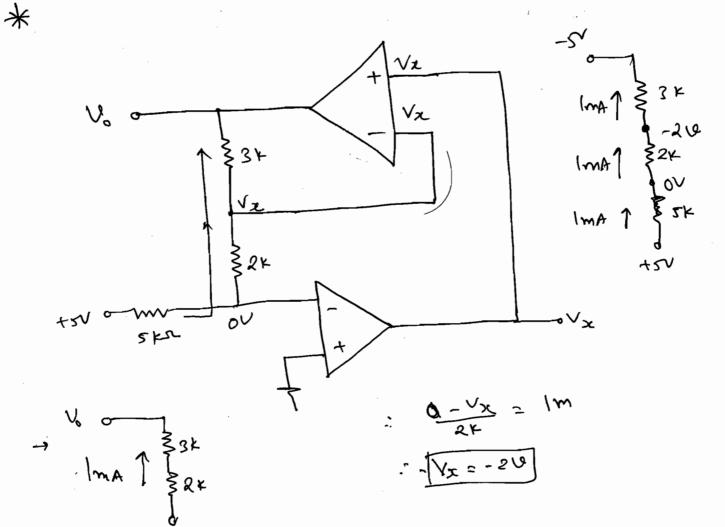
$$R_0 = \frac{R_2 + R_3}{1 + \frac{R_2}{R_1}}$$

.

*

V02 - 50





((

C

()

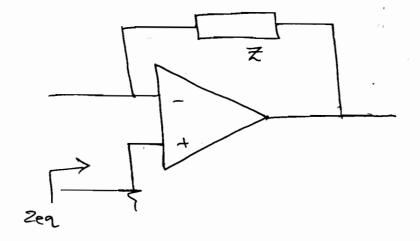
$$\frac{0-V_{N}}{5} = \frac{V_{N}+4-V_{0}}{0.5}$$

3 K

$$\frac{5}{5} - \frac{2^{1/3}}{2^{1/3}} = \mathcal{X}\left(\frac{2}{5}^{1/3} + 4^{-1/3}\right).$$

$$\frac{-\frac{V_0}{255}}{\frac{2}{5}} = \frac{2V_0 + 20 - 25V_0}{5}$$

$$\frac{255}{-10} = \frac{5}{100} = \frac{25}{100} = \frac{25}{100} = \frac{25}{100} = \frac{25}{100} = \frac{100}{100} = \frac{25}{100} = \frac{100}{100} = \frac{100}{$$



 \bigcirc

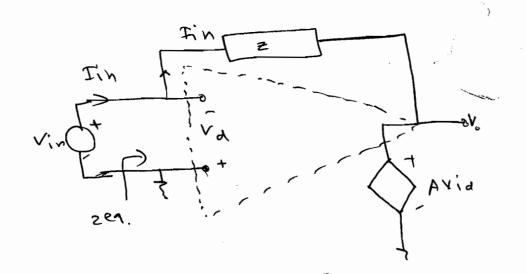
()

()

()

(=)

111



 $\Rightarrow V_{in} - Z I_{in} - A V_{id} = 0$ $\therefore I_{in} = \frac{V_{in} - A V_{id}}{Z}$

But, -Vid - Vd = 0 : Vd = Vin

: Tin = Vin + Avin.

: Zer= Vin 2 1+A

NoTE: Miller's ethert is seen only top - 37 inverting amplifier. e.g. CE ampriher suppers from miller's ettect. - These is so miller, i effect for CB and CE amplifier. 1K2 * $\frac{2k}{1+A} = \frac{1}{1+100}$ $Rea = \frac{1}{1+A} = \frac{1}{1+100}$ 2010.000 * :. Zer= 1+A = 1+1000 = SL 1+1000 : Shea = Shea = 141000 = 141. zer IMF Zer= 1+A= : 8kc = 1 = 8c. zer Cen = CIAA : (1+A)C. miller's mutipication Con = (1 F)

(

Missioner Co C Thuch -

Z= Pm C.

()

 \bigcirc

(Ē)

(

 \bigcirc

0

(E)

 \bigcirc

()

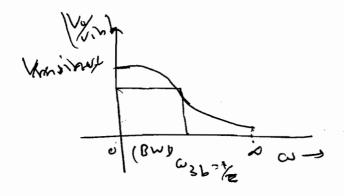
[2117c]

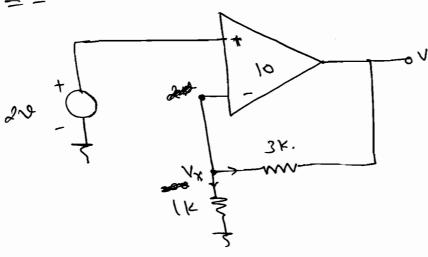
os f > high (21/21/20 50 5.1.

Su, Vo= 0.

f > Low / attract = 0 50 0-1.

: 50, Vo = 51NUE.





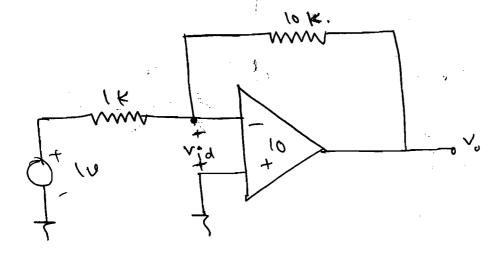
AOL= 10 Find Voza

111

..
$$V_{0} = 20 - \frac{5V_{0}}{2}$$
.

$$\forall A_{v} = \frac{v_{o}}{2u}$$

Ex 2 Fina Vo. AOL= (0.



V= 1000.

 $(\hat{\cdot})$

Diode Applications:

A diode is turward bias when amode is more the that costhode.

 $\begin{array}{c|c}
\hline
\hline
\hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline
 \hline$

piece-wise Lineurs model. if I = tve -> F.B. I= Ne -> R.B.

But I never -ve So I = O => R.B.

Ex-1 Check Whether Diode is F.B. of not. asso find the vame of current frow:

(1)

6 V 3 V 3 V - 5 V

Let 21 5.c. 30.

: I = +8 +5

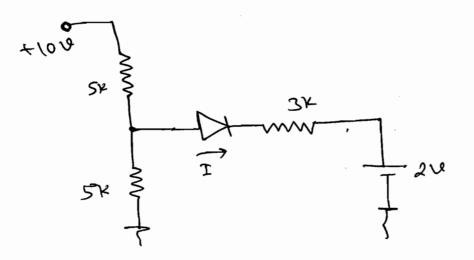
: 1= +1.5 mA

50, P.B.

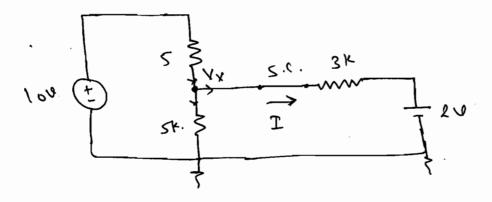
So, FiB.

and ago

Ex-3



77



$$\frac{10-\frac{1}{5}}{5} = \frac{\frac{1}{5}}{5} + \frac{\frac{1}{2}}{3}$$

$$\frac{1}{5} - \frac{1}{5} = \frac{1}{5} + \frac{1}{5} - \frac{2}{5} \cdot \frac{1}{3}$$

$$I = \frac{\sqrt{x-2}}{3k}$$

$$\therefore T = \frac{40 - 2}{11}$$

0

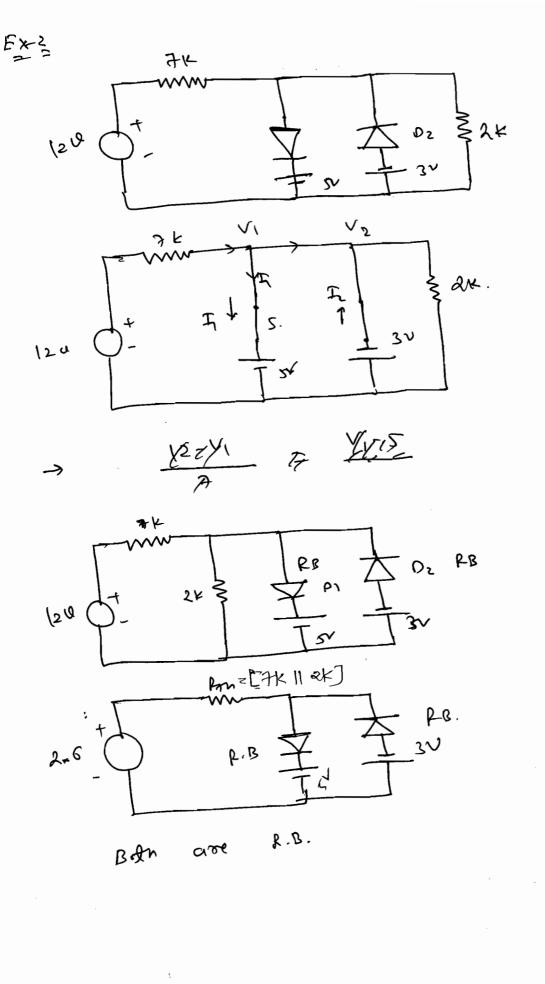
 Θ

٥

 \bigcirc

(...

I =0- H MA



()

(..

()

(

. .

 Θ

 \mathbf{C}

(..

. . .

/*·-

(.

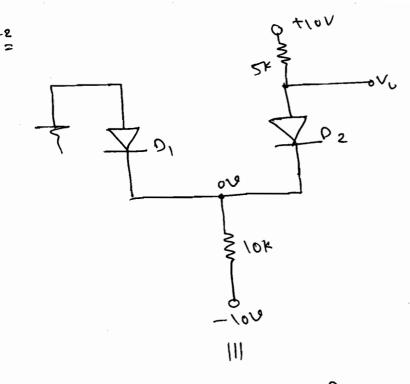
(

C

Ex-1 Find Vo, Diode is ideal 10/vF PXD OPEYOR Id= Fe Vo= Ve In [To] Jug operation NIF FX =

30 Diode experience more potential difference 50, it is on admand D2 03 is over.

Ξ



()

(_)

()

()

()

()

 \bigcirc

()

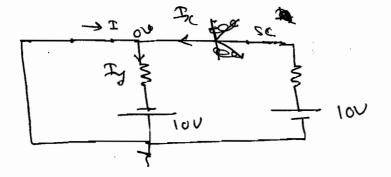
()

()

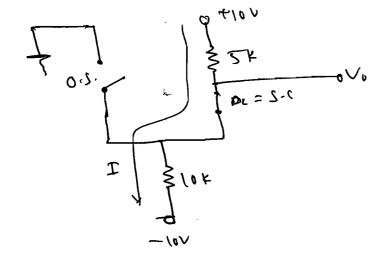
()

 \bigcirc

Ans: Let Test-D,



$$T = \frac{0 - (-10)}{10k} - \left[\frac{10-0}{5k}\right].$$



$$\frac{\sqrt{6-(-6)}}{10}=I.$$

$$V_0 = \frac{40}{3} - 10$$

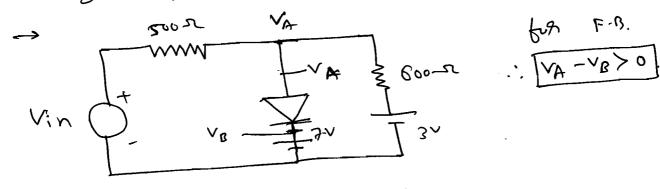
$$\left[V_0 = \frac{10}{3} U. \right]$$

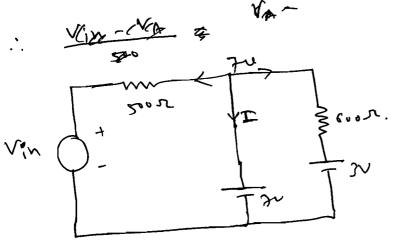
$$T = \frac{10 - (-10)}{15}$$

$$\dot{\mathbb{T}} = \frac{20}{15}.$$

:
$$I = \frac{4}{3} = 1.33 \text{ mA}$$
.

Ex & Find the minimum voltage Vin to for Diode to be FB.





.: so Diode Di is

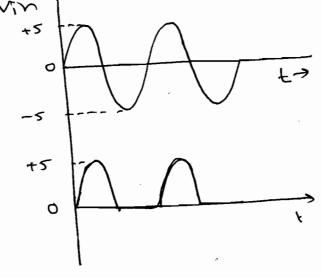
€

€;`

<u>(.</u>)

•

or cliping circuits: [limiters] 49 & Clipperes -> Clipper is a circuity which cuts the possion Of the required axiveform. . Vx= Yin : Vin sunge: -5 to +5 Vx runge: -5 to +5 Vo junge: of +5:



· 1 × = 1, N-50.

Vin ounge: -5 to +5v.

Vx ound: -7 to 3V.

No gange: 0 to 24.

* du Vir Vin D+ Vx Vx = Vintz. Vandunde: -5 to to V Voc runge: -3 to to l. 0 Vu sumor: ofo 7v. $(\dot{})$ Vin>2-6 Vin>2-6 FB 0 t VOFAV () (77.1 • : 1/x=-1/in. Vin & R W.

Vin - 2 + 4x=0 : Yx = 2- Yin. : Vin dunge: -5 to +50 Yx Range: 7 to -3. Vo Runge: 0 to 3. ーナもし $\sqrt{x} > 0$ 2-11>0 Vin < 27. fox F.B. Vin +24 + 4x = 0 : 1x = -1 W-50 Vx runge: 3 to - 7 V. Vorange: oto-74. Vx70 - Vin-50 > 0 VIN < -80. $v_0 > 0 + 0 - 3 V$

* Sketch $\begin{array}{c|c}
\hline
 & & \\
\hline$

Vin - 4x = 0

2 Vx=Vin.

=, Vin sunge: -5 to +5

-5 to 45. Voc dunge!

()

 \bigcirc

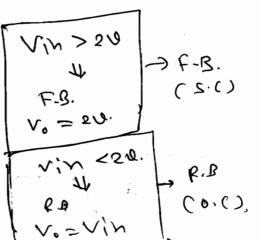
-s to o. ~ sande:

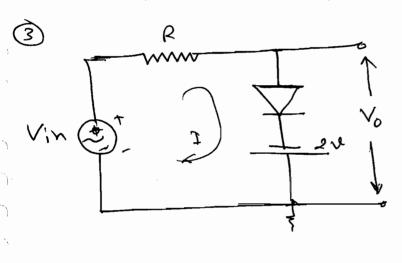
t.B I >0 T = Vin-0 I = Vin , >0 -: [NINSO] BO Vinso R.B.

: No = NIN I NINZO Vo= 0, Vinto

Harr

2 = Vin-2.70 : [N/N > 5 A) -3 EB R.B. Vin < 20, ~0=2



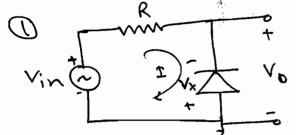


$$\mathcal{I} = \frac{\lambda^{1} + 5}{\lambda^{1} + 5}$$

$$\frac{Vin + 2}{P} > 0$$

$$Vin > -2 \rightarrow F.3.$$

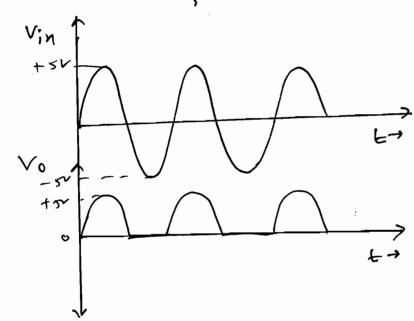
$$V_0 = -24$$

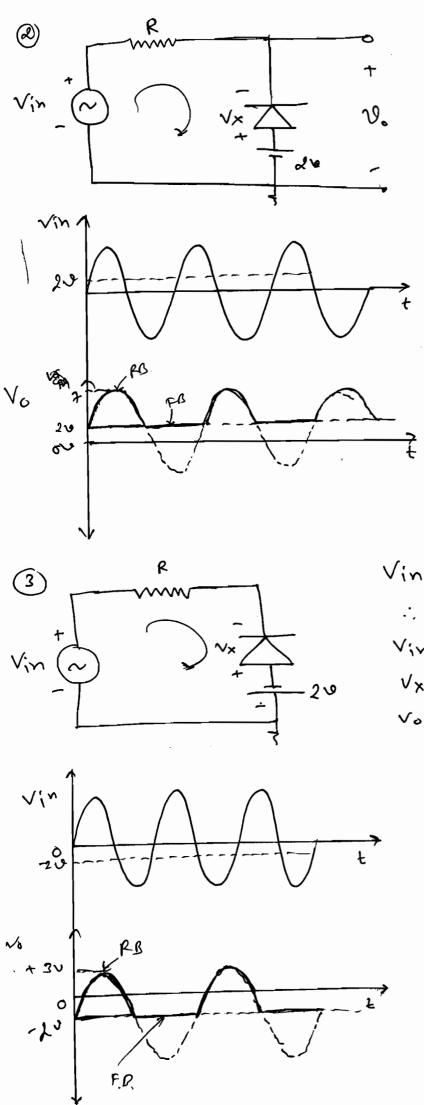


-. Yx = -Vin

Vin sunge: -5 to +5 Vx sunge: +5 to -5.

Vo sunge: 8\$00.





Vin +vx -20 = 0 : Vx = 2-Vin.

· Vin sunge: -5 to 5 40 √x sunse: 7 to -3~ Vo sunge: 7 to 0 1.

√x>0 → F-B.

 \bigcirc

 \bigcirc

(

0

0

$$2 - V(N) > 0$$

$$V(N) < 2 U$$

$$V_0 = 2 U$$

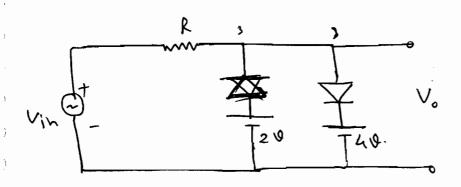
$$V(N) \ge 2 U$$

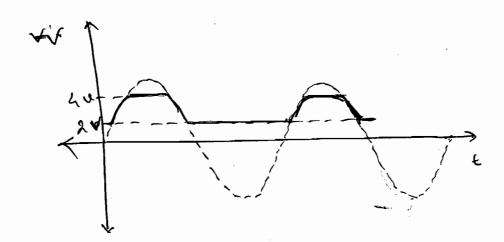
$$V_0 = V(N)$$

Vin + Vx +24 =0 . Vx= -2 -Vin.

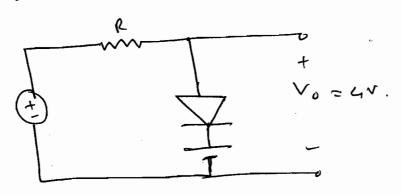
Vin Junge: -5 to+5. Vx ounge: +3 to -70 Vo sum ge: +3 to 04. √×>0 → F.B.

$$\begin{array}{c} A^{\circ =} A^{\circ \times} \\ A^{\circ \times} & \rightarrow B^{\circ} \\ \hline A^{\circ \times} & \rightarrow B^{\circ} \\$$

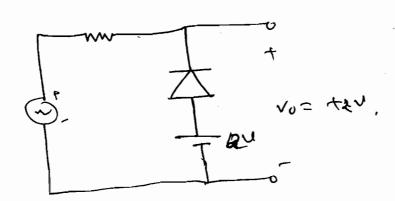




1) couse-1: Vin >4 -> Vo=+4V.

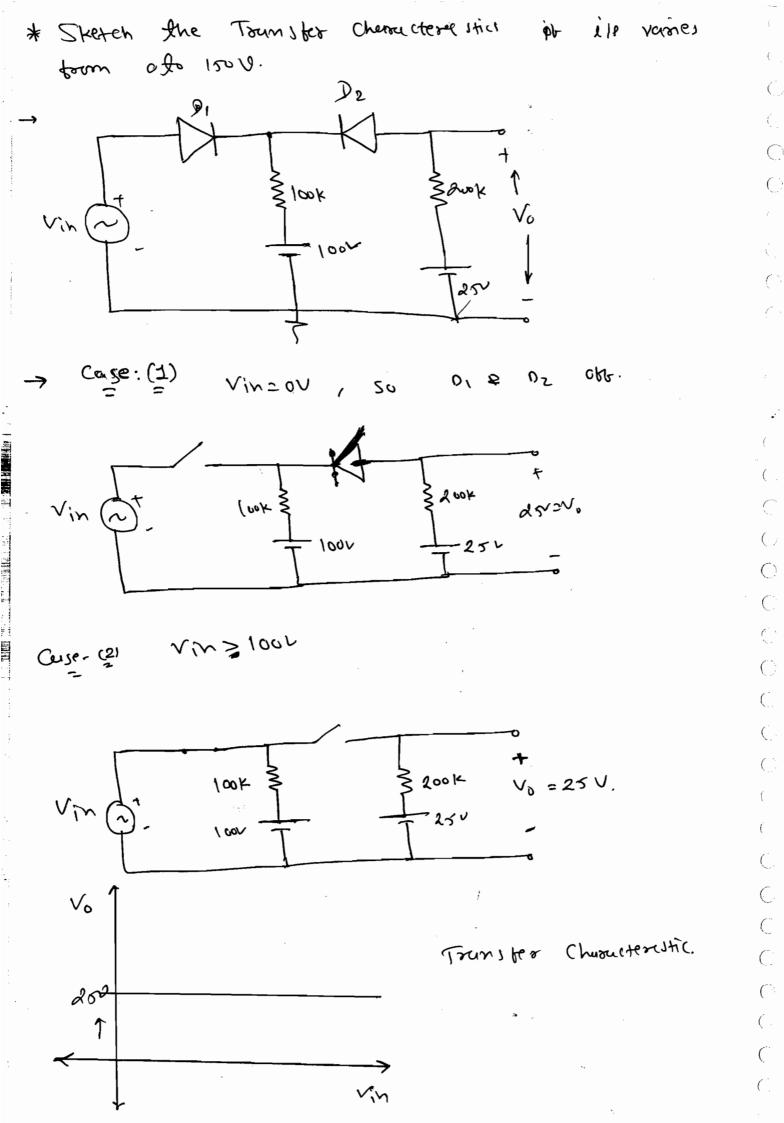


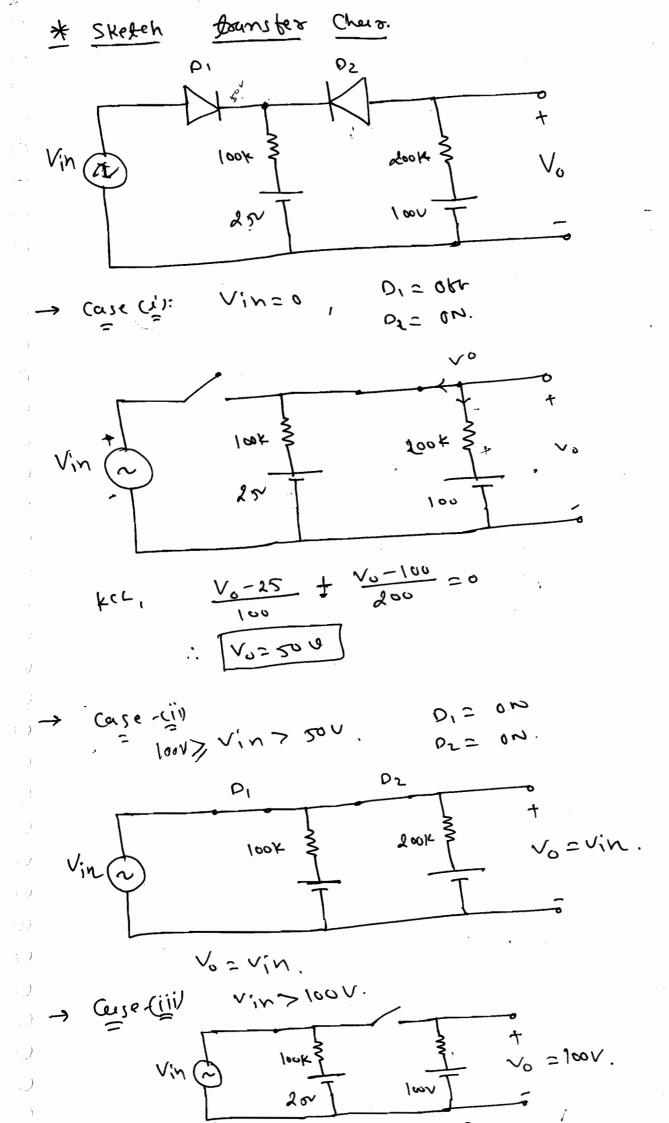
@ Winch J No= +sn.

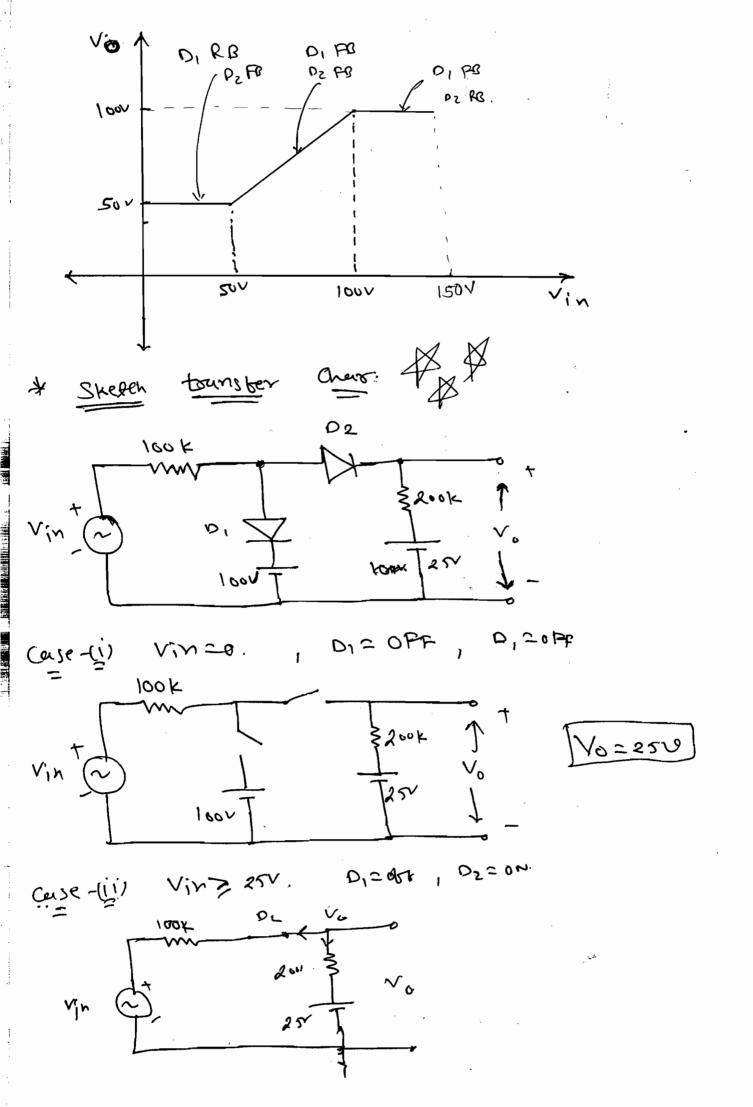


ause-3 2 < Vin 53.

Both (Ps) Vo=Vin,







(°.

(°.

0

(··)

()

(,

(

_

C

. .

 \bigcirc

 \bigcirc

(°)

()

$$\frac{V_0 - V_{in}}{100} + \frac{V_0 - 25}{200} = 0$$

: 2vo-2vin +16-25=0.

:. 34° = 2 Vin +25.

: Vo= = Vin+ 25.

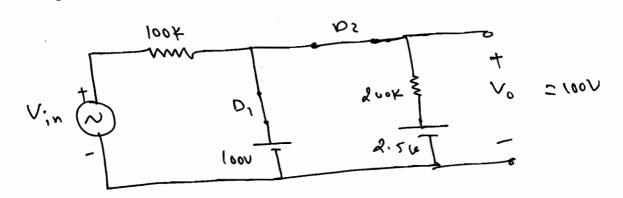
Now, max rune of Vo= 100V.

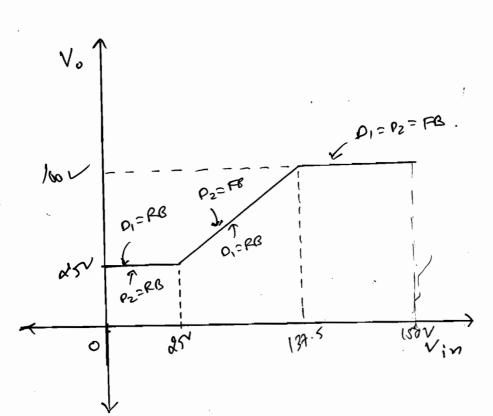
: 100 = 2 Vint 25.

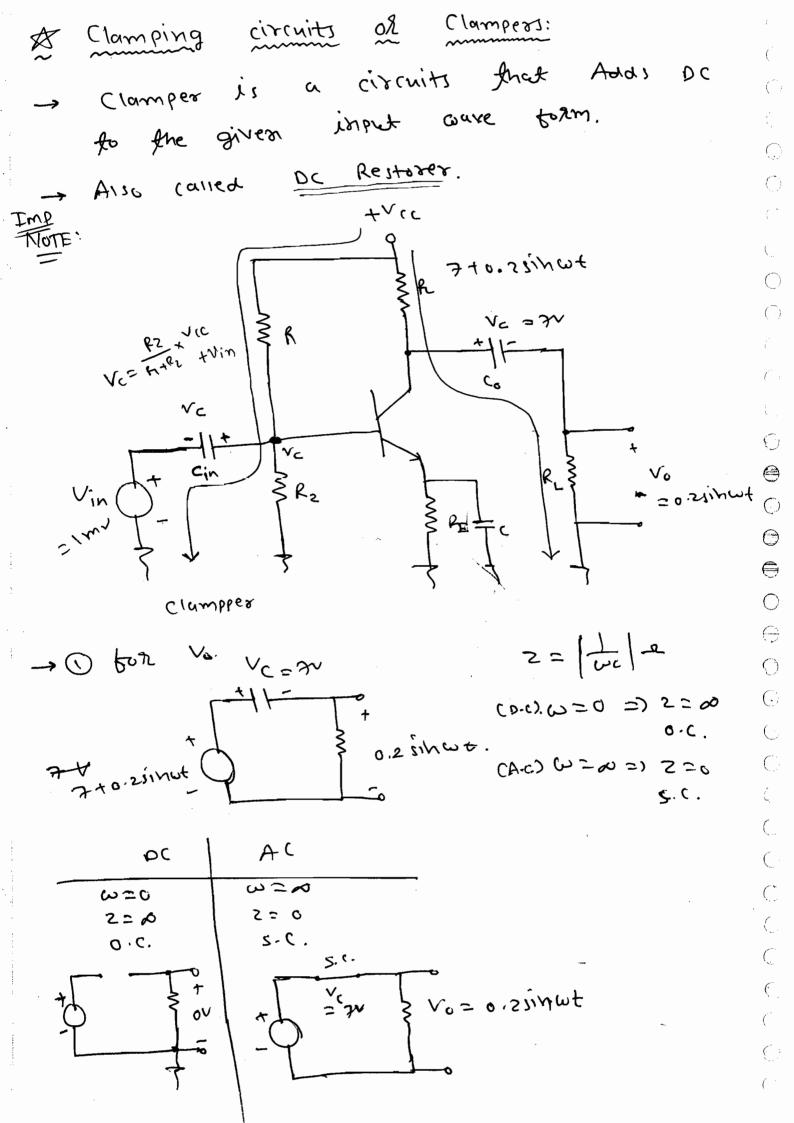
:. 300 -25 = Vin

:. Vin= 137.5 10. => V.=100V.

= when Vin7 137.5. 01 = 01, 02=01.

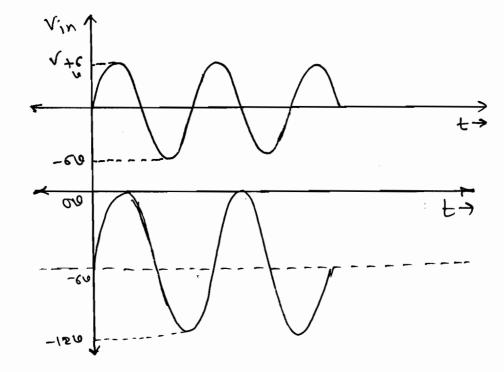






-> So, at old Capacitas is used to block DC Component and allowe Ac Component. @ At lip: * It are dong's + Vcc use Capacitos Ci then very small input volture available. and thereone a tre device is in cut of region. -> Mow, be cause of Capacitose It store the oc volture and this De voltuse are world Add 00 to the input so that DC biusino Re Vin = Vc=Vo. point - shift from mall rune to jurge raine so fact the Device & will come : Vo= Re XVCC into active resion. Ic 1 sut. So, Corpucitor is - used for the BINZINS: of 26 cribbis input and Adding here act as some Activ clamper. DC. cutob DC biasing

This simple Steps to douce Ine output: (i) Find the capacitor Voltage ve in its (\cdot) Steady state. Replace diode with open switch and () draw the output waveform. (.)VA = Vin-Vc -5 to +5 VA oun ze: -10 \$000. \bigcirc c negs. Vc = 6v Vin sunge: - (toto). range: -12 to ev.

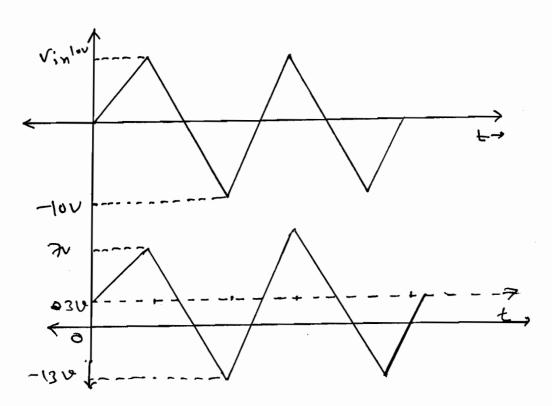


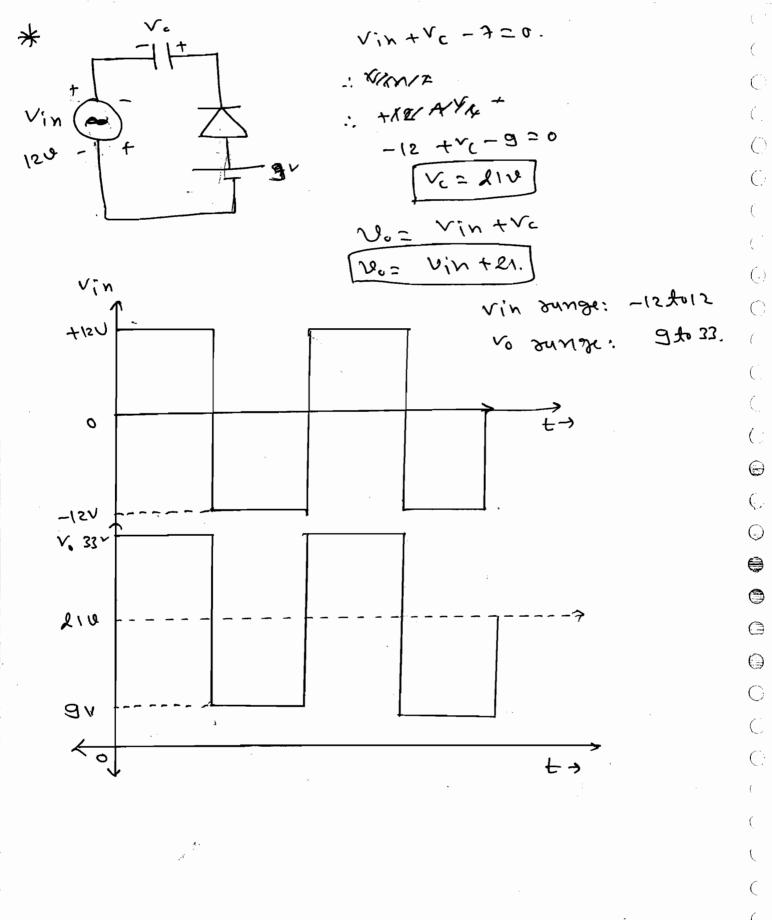
Vin Reng: -5 to+5.

Vin Reng: -5 to+5.

Vo = Vin-3 2.

Vo sunge: 7 to -132.

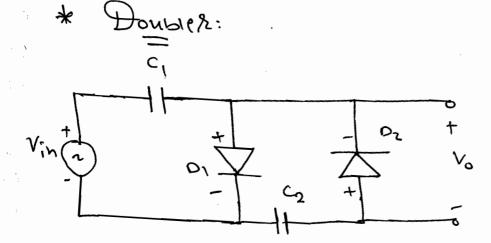




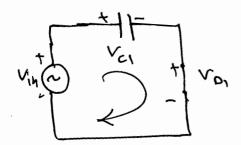
10 Voltage Muliplier:

Vin= Vmsinwt (Ac) Vo= nVm (DL)

M=2,3,4,...



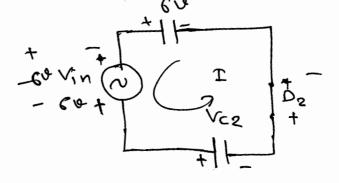
=) During +xe (y(1e



· Vin - 60 - Vo1= 0. [when vo]

N'n sunse; - exote

Voi runge: -12 to 00



: Vin -vc2 + 6 =0

Vcz= Vinte.

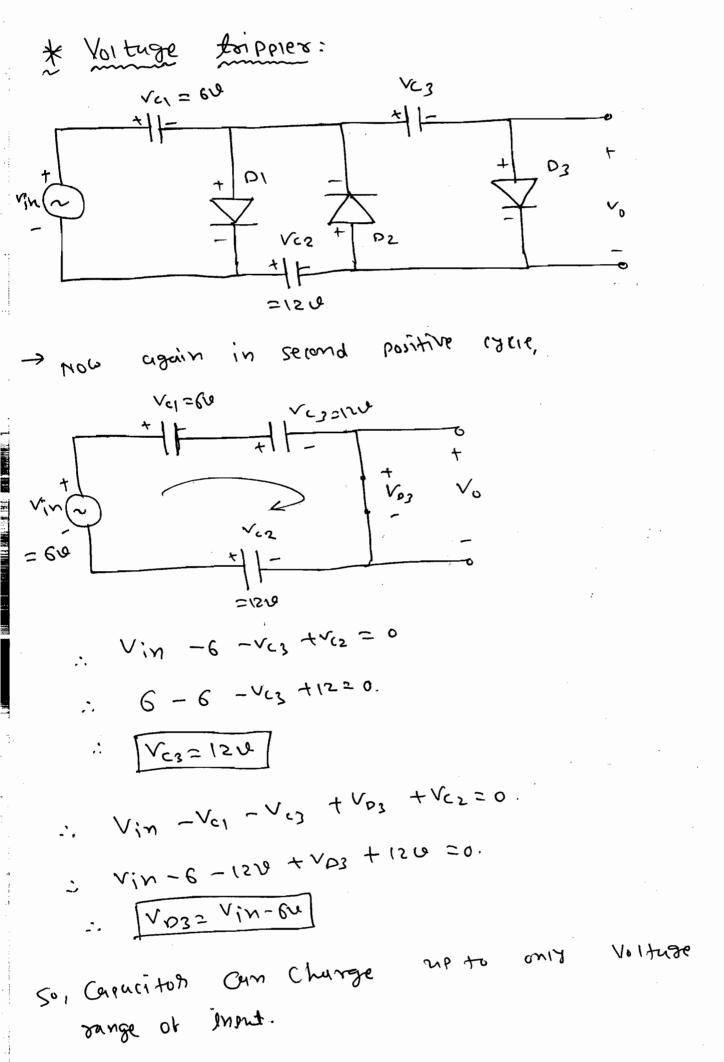
·· Vc2= 6+6= 120.

:. Vin -6 + Voz + V(z=0

: Vin - 6 + Nos + 15 = 0

Vin surge: -6 to +60

Vor sunge: oto rev.



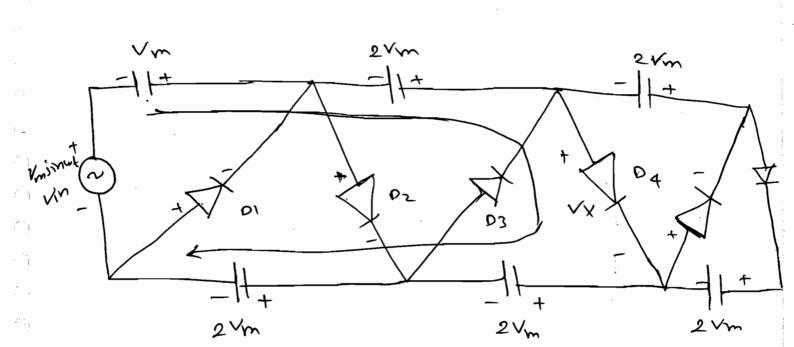
(

(-)

 \bigcirc

€)

◐



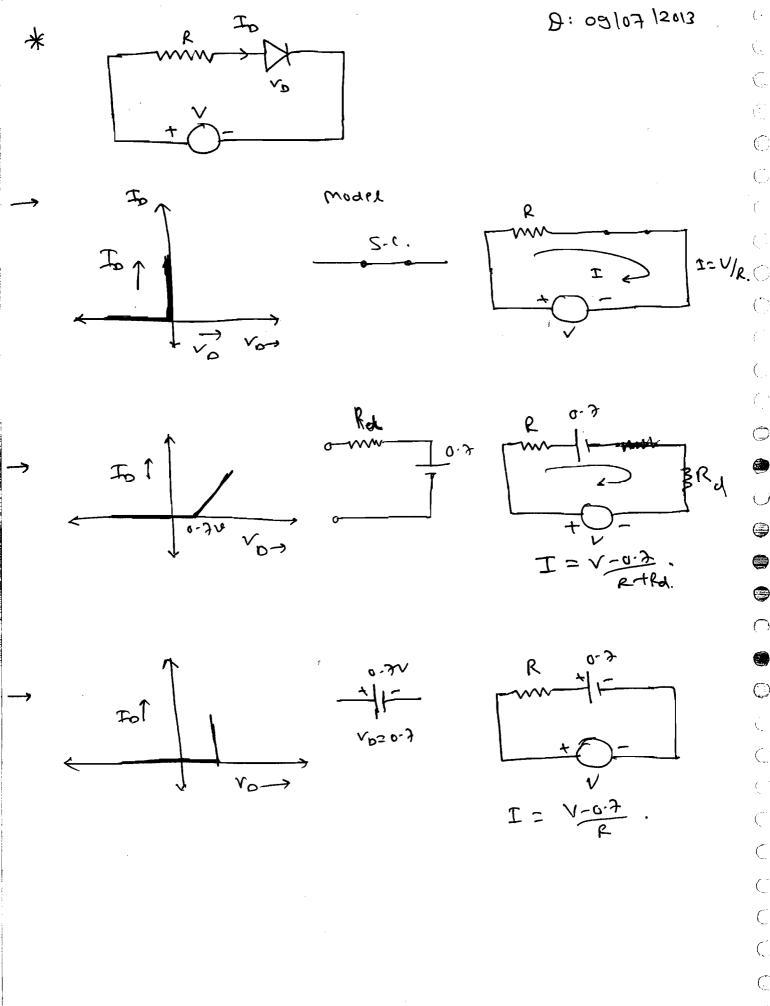
 $Vin + v_m + 2y_m - v_x - 2y_m = 0$ $Vin + v_m + 2y_m - v_x - 2y_m = 0$

*

:

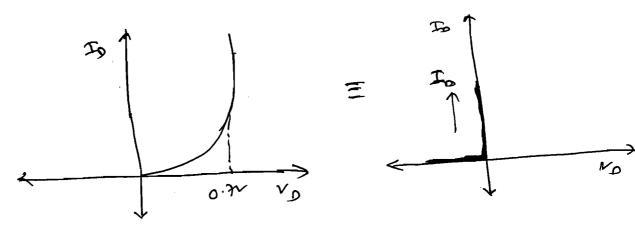
(, ,

1



(. •

(·)· (.''



- -> When diode is F-B. the OP-AMP is in close loop contiguoration.
- -> But initial stage input voltage is very small time, and so diode is our took a very small time, and open fook configuration. So op-Amp is is in open fook configuration. So

:. Vo= 106 x (1mv) = 1000V.

But, Vo never excell & Vsut So.

:. Vo = -Vsux (: inverting comp.).

NOW, this -Vocat make diade F.B. and op-Amp is now in Close peop consignization.

→ 50, within a no time. diode will be in F.B.

Condition i.e. 0.7 & required to firm on the

diode instead ob 0-7 18.

So, for I ev, diode win be on and it is look like a ideal diode. Or shown in figure.

(:

(

()

()

(:

()

(),

(/

 \bigcirc

()

 $(\overline{\cdot})$

(

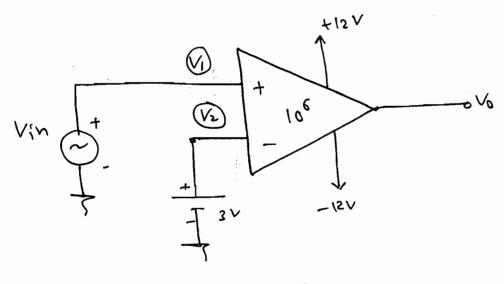
()

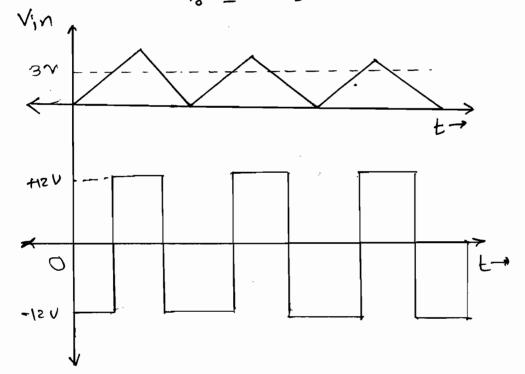
()

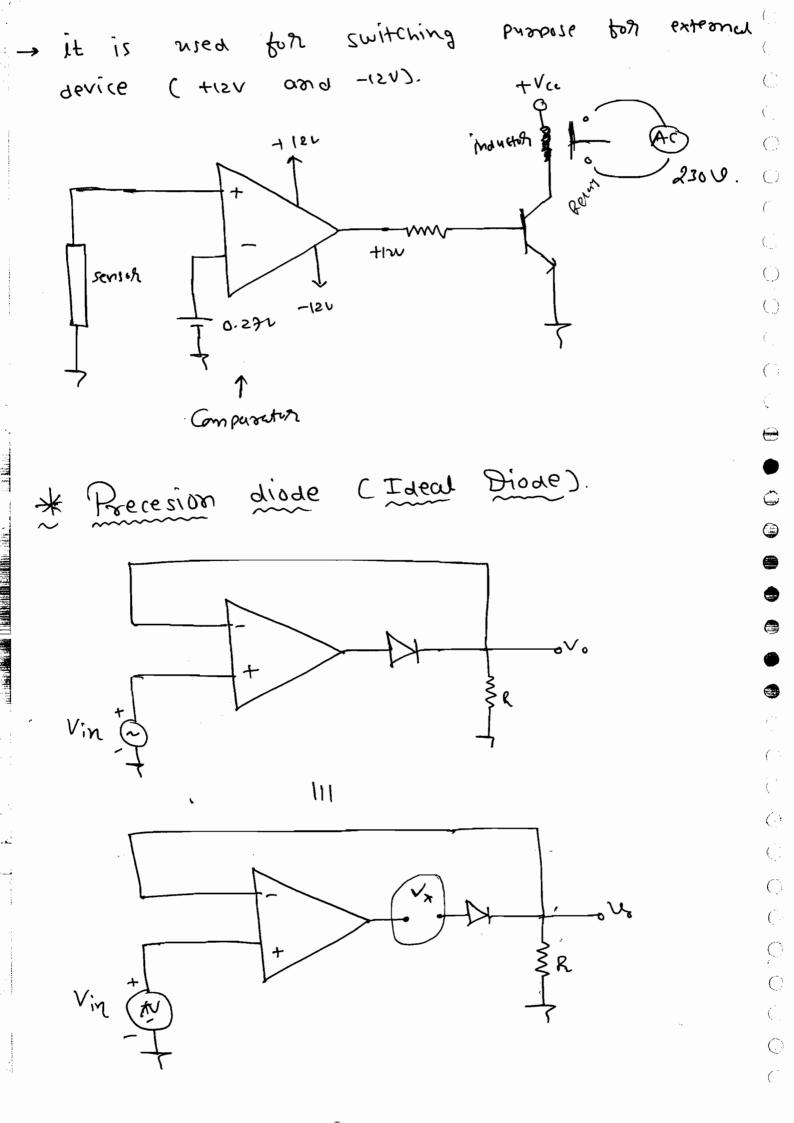
Note:

- The Op-Amp is in its + Close loop (feed back) configuration.
- -> When the diode is on their apply vistnal
 - is in open loop Op-Amp.
 - in the feedback asso.
 - → When diode of BJJ use doiven by OP-Amp then Chusu is of changing to ideal diode.
 - -) Biode and BIT can be driven by Op-Amp.
 - op-Amp is driver.

71

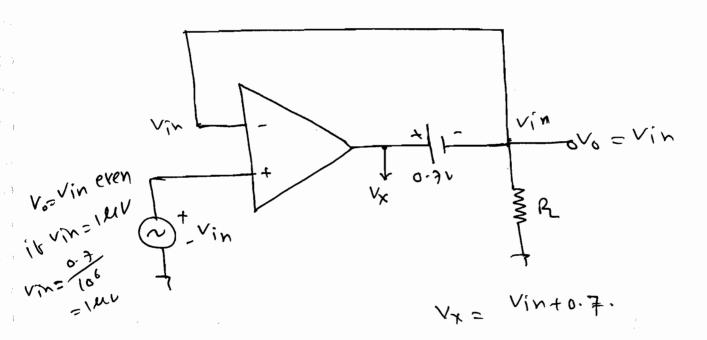






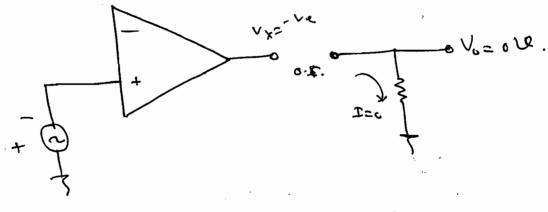
case-1 When Vin70 => Vx is Pos.

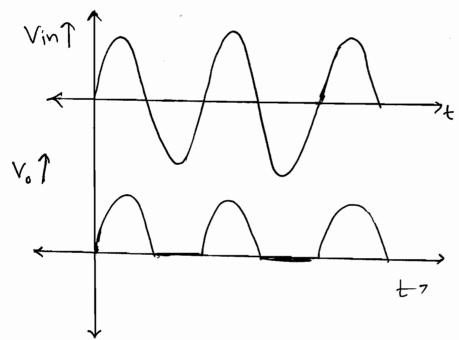
Diode is F.B. (NGJ. FIB).



Case-(i) Vinto - Vx is neg - Diode is R.B.

()



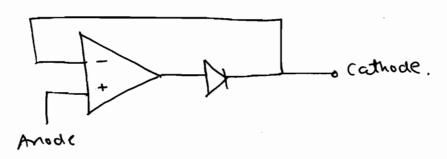


Half Waxe

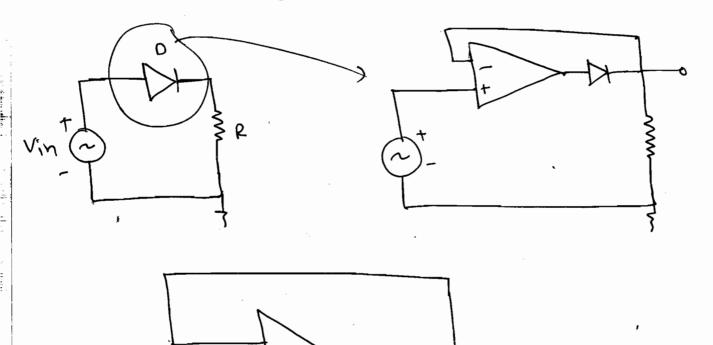
Rectibier.

NOTE: This circuits sectibles all Voltage Vin Siignty greater than $\frac{0.7}{AOL} \simeq \frac{0.7}{100} \simeq 14V$

*



(ideal diode)



Ideal diode = Openp + Diode.

· (athode

 \bigcirc

 \bigcirc

0

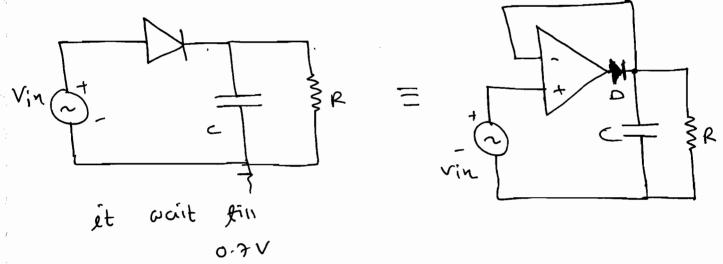
 \bigcirc

(:

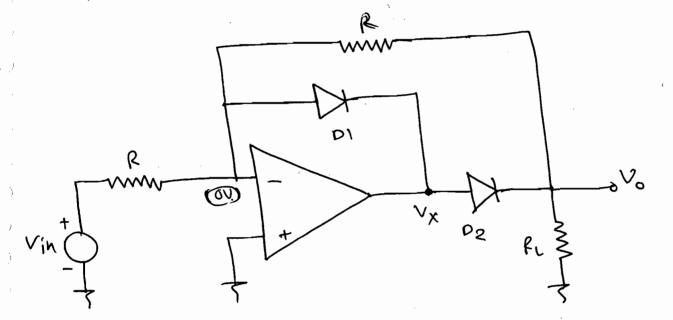
()

* Peak detector (envelope detector)

-> Au Butters have current guist.

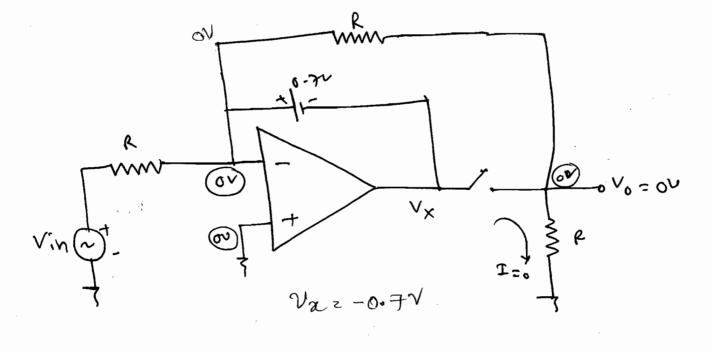


* Improved Haib Wave Rectifier:



Case-(1): When $V_{X} = +Ve$ $V_{X} = -Ve$.

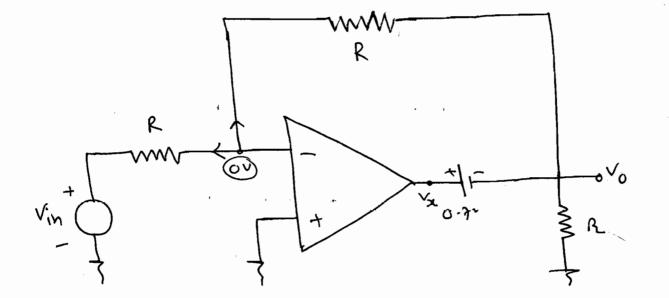
> So, O1 → F.B. O2 → R.B.

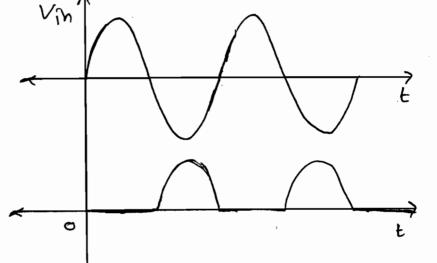


$$V_{in} \Rightarrow -ve$$

$$v_{x} \Rightarrow +ve$$

()





R

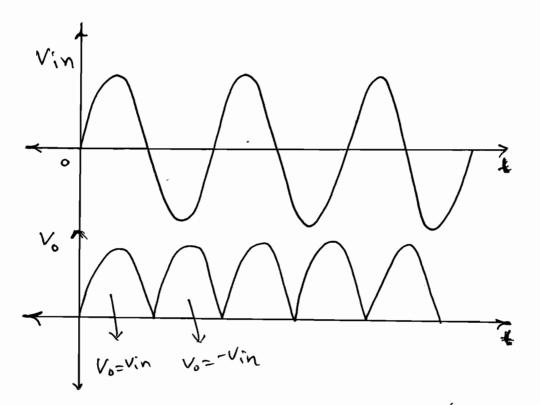
Di= of Ca76- 3: D2=0N. V_B $\frac{0-Vin}{p} + \frac{10-VB}{2^p} + \frac{0-VB}{R} = 0.$: - 2 Vin - VB - 2 VB = 0 Vg= -2. Vin. $\frac{\sqrt{B-0}}{2R} + \frac{\sqrt{B-0}}{R} = 0.$ = \frac{V_B}{2R} + \frac{V_B}{R} - \frac{V_0}{R} = 0.

0

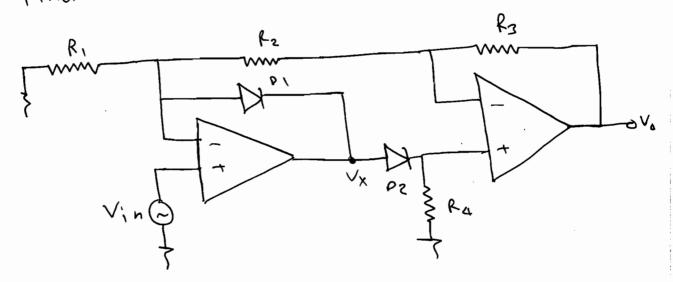
0

 \bigcirc

 $V_0 = \frac{3}{2} V_B.$ $V_0 = \frac{3}{2} (-\frac{2}{3}. V_{in})$ $V_0 = -V_{in}$

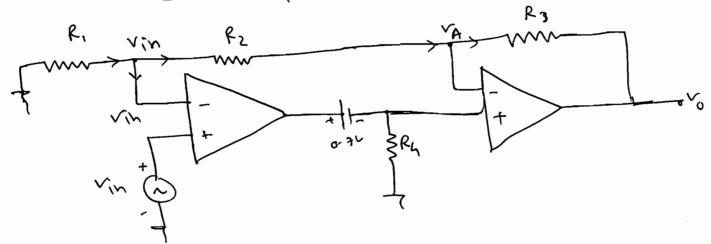


Ex-1 Find 10 if Vin=tue & Vin=-ve.



Ans: (i) When Vin = +ve => Vx= +ve.

DZ it FB , D, -> RB.



$$\frac{O - \sqrt{in}}{R_1} = \frac{\sqrt{in} - \sqrt{\epsilon}}{R_2}$$

$$\frac{\sqrt{\epsilon}}{R_1} = \frac{\sqrt{in}}{R_1} + \frac{\sqrt{in}}{R_2} - \frac{\sqrt{\epsilon}}{R_3}$$

$$\frac{\sqrt{in} - \sqrt{A}}{R_1} = \frac{\sqrt{A}}{R_1} + \frac{\sqrt{A}}{R_2} - \frac{\sqrt{\epsilon}}{R_3}$$

$$\frac{\sqrt{in} - \sqrt{A}}{R_1} = \frac{\sqrt{A}}{R_1} + \frac{\sqrt{A}}{R_2} - \frac{\sqrt{\epsilon}}{R_3}$$

$$\frac{\sqrt{in} - \sqrt{A}}{R_1} = \frac{\sqrt{A}}{R_2} + \frac{\sqrt{A}}{R_3} - \frac{\sqrt{in}}{R_2} + \frac{\sqrt{in}}{R_3}$$

$$\frac{\sqrt{in} - \sqrt{A}}{R_1} = \frac{\sqrt{in}}{R_2 + R_3}$$

$$\frac{\sqrt{in} - \sqrt{A}}{R_2} = \frac{\sqrt{in}}{R_2 + R_3}$$

$$\frac{\sqrt{in} - \sqrt{A}}{R_2} = \frac{\sqrt{in}}{R_2} + \frac{\sqrt{A}}{R_3}$$

$$\frac{R_3}{R_2 + R_3} = \frac{\sqrt{in}}{R_2 + R_3}$$

$$\frac{R_3}{R_2 + R_3} = \frac{\sqrt{in}}{R_3}$$

$$\frac{R_3}{R_2 + R_3} = \frac{\sqrt{in}}{R_3}$$

$$\frac{R_3}{R_3 + R_3} = \frac{\sqrt{in}}{R_3}$$

$$\frac{R_3$$

٩

٣

(

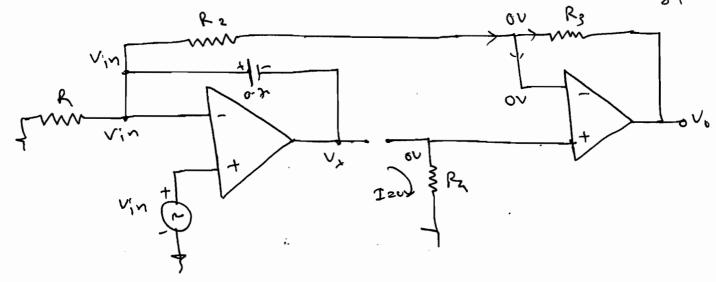
$$\frac{O-Vin}{R} = \frac{1}{R_2 + R_3}$$

$$\frac{-Vin}{R} \frac{(R_2 + R_3)}{R_1 = R_1} = R_1 (Vin) - RV_0.$$

$$\frac{R_1 = Vin}{R_1 = R_2 + R_3}$$

$$\frac{R_1 = Vin}{R_1 = R_1 = R_2 + R_3}$$

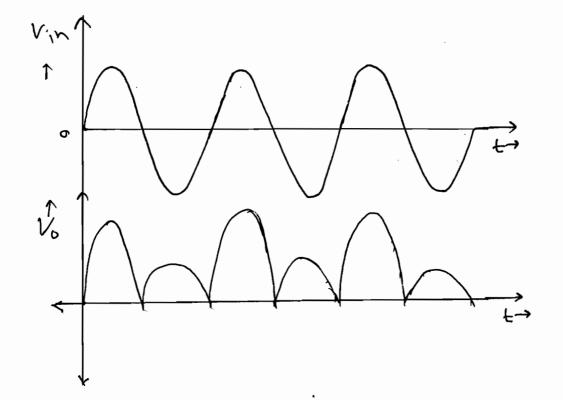
② when $\forall i n = -ve$. $\forall x \Rightarrow + ve$. $p_2 \rightarrow i \cdot B$.

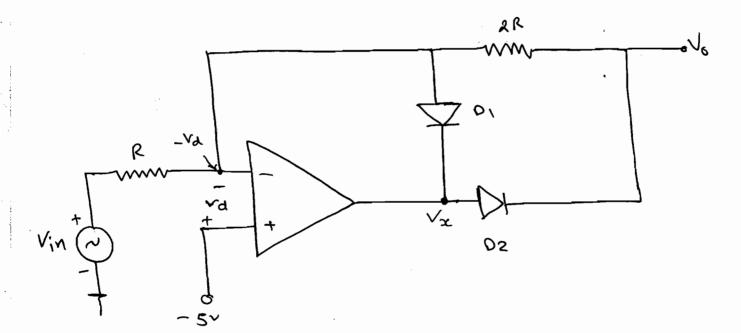


$$\frac{\sqrt{in-0}}{R_2} = \frac{0-V_0}{R_3}$$

$$\frac{V_o}{V_{in}} = -\left(\frac{R_3}{R_2}\right)^{\frac{1}{2}}$$

$$V_0 = -\left(\frac{R^3}{R_2}\right)ViM$$

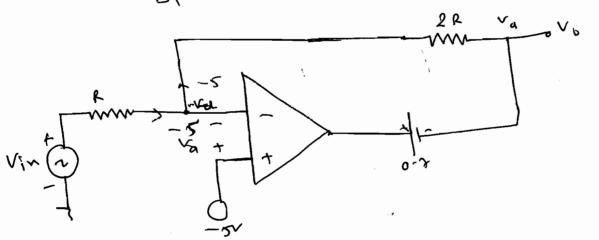




Ans: Case-(i) Varo, Va= -Vin-5 >0

Varo => Vx=+ve.

D, > R.B. D2 > FB.



Vin-(-va) = -va-vo va=5.

: 2 vin tava = - va - vo

3 rd = - Vo- 2 vin.

5= -vo -2vin.

15 - (15 truin).

for vinc-s.

 $(\hat{x}_{i,j}, x_{i,j})$

(__

(1)

()

()

 \bigcirc

9

 \bigcirc

(...

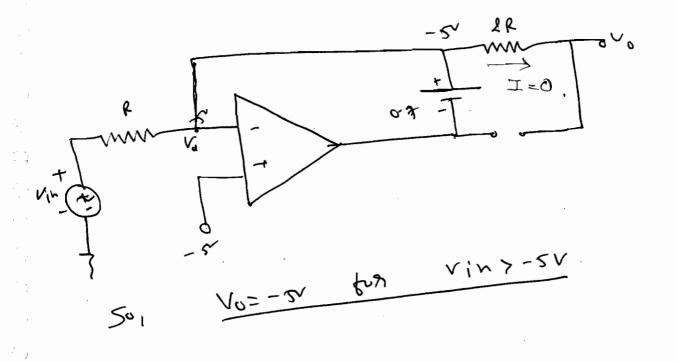
()

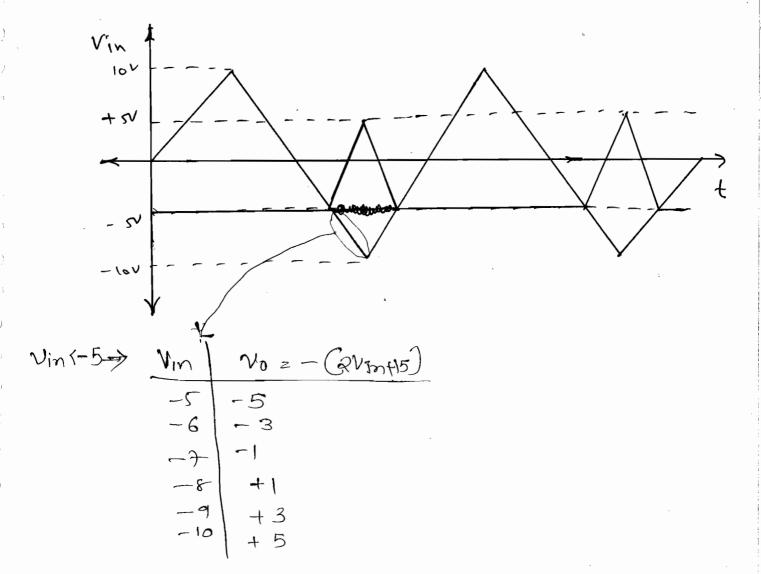
0

(

Vin 3-5 => 01= R.B. Nd <0 02 = R.B. Vx=-Ve

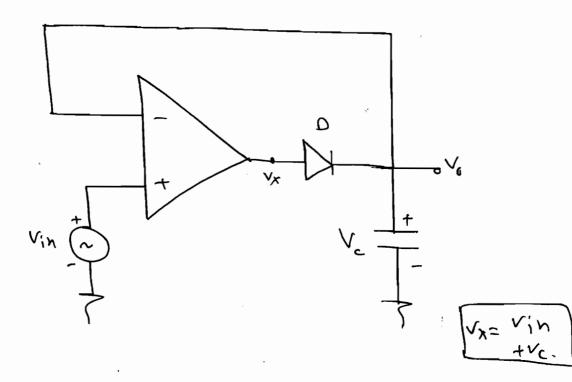
0





* Peak Detector:

学



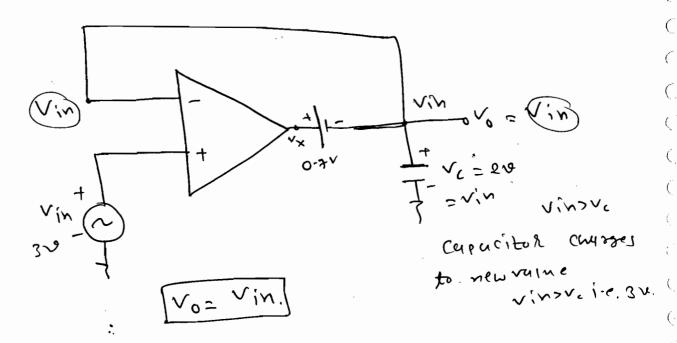
⇒) (rise (j).

when

 $\sqrt{i_h} > \sqrt{c}$.

Vx is tre.

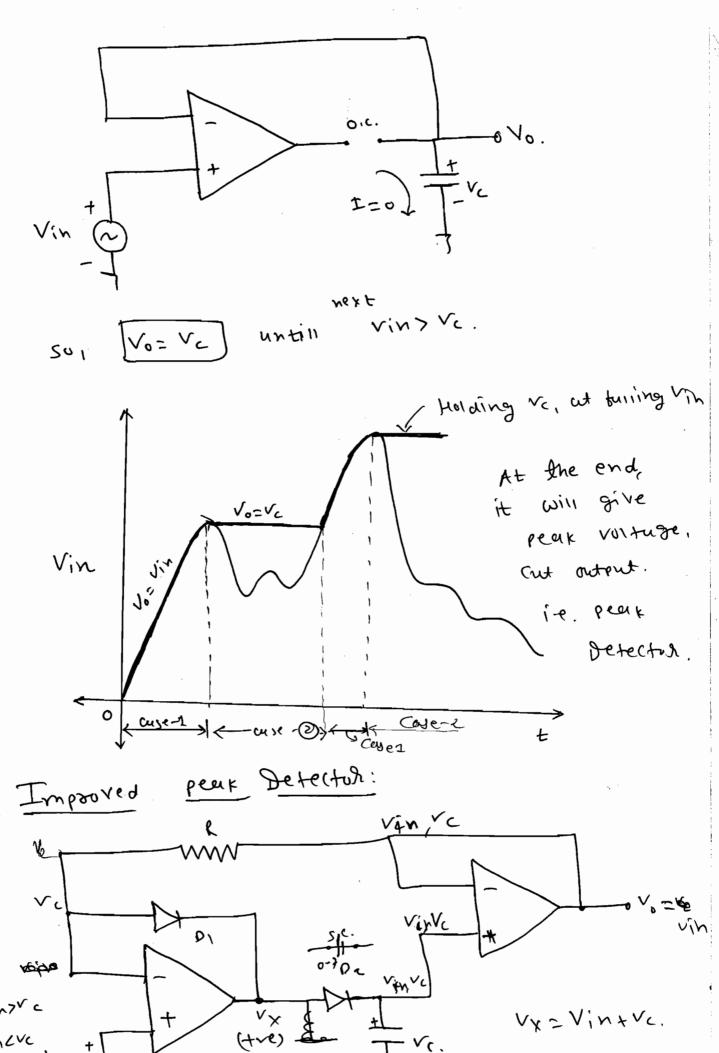
0 -> F.B.



case- 2: When Vin CVc.

D > R.B. C : Vx=-ve),

divde - R.B.

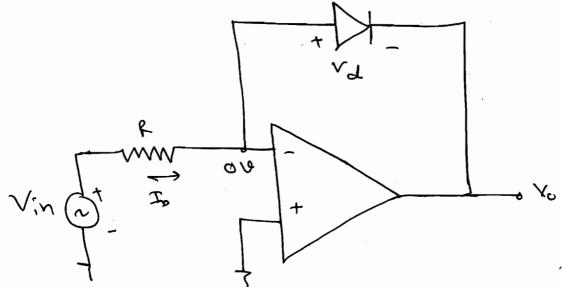


A Log

Amprilier.

Valve Id= I, e

Vd= Vt In (I)



MOW,

$$V_0 = -V_t \ln \left[\frac{Vin}{kT_i} \right]$$

 $\therefore I_0 = \frac{\sqrt{i_N - 0}}{R}$

()

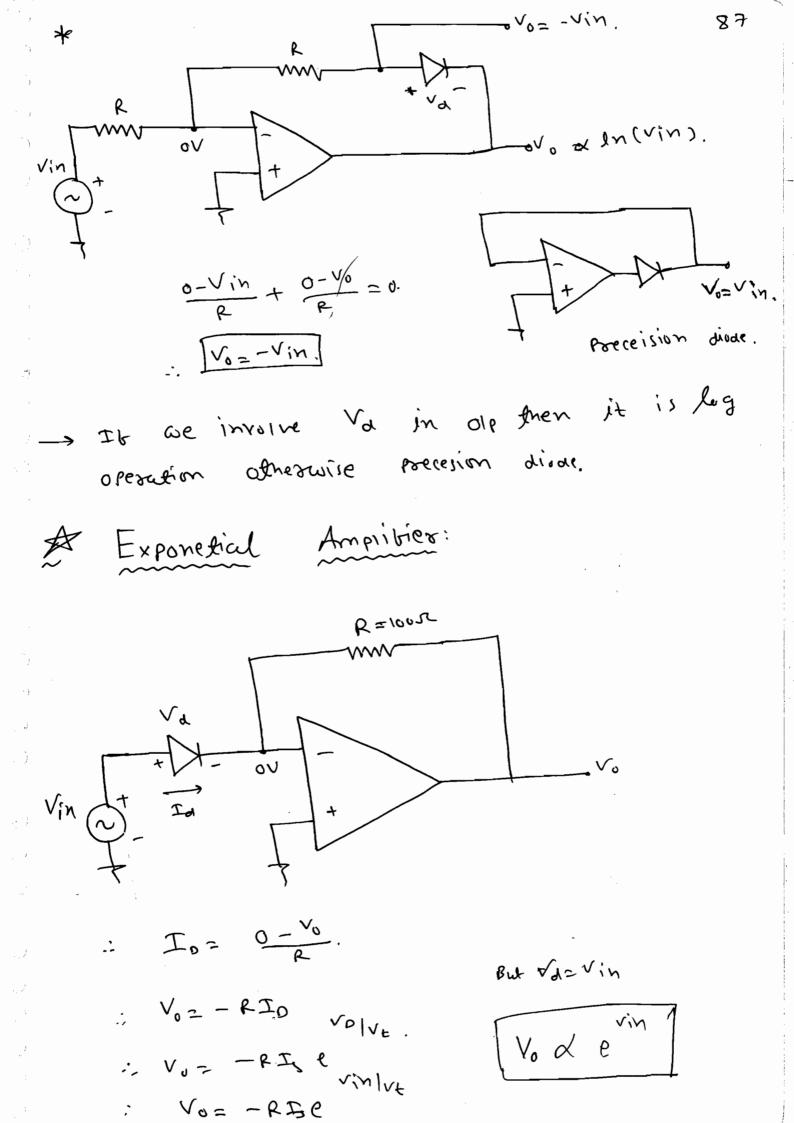
(; (;

(E)

() ()

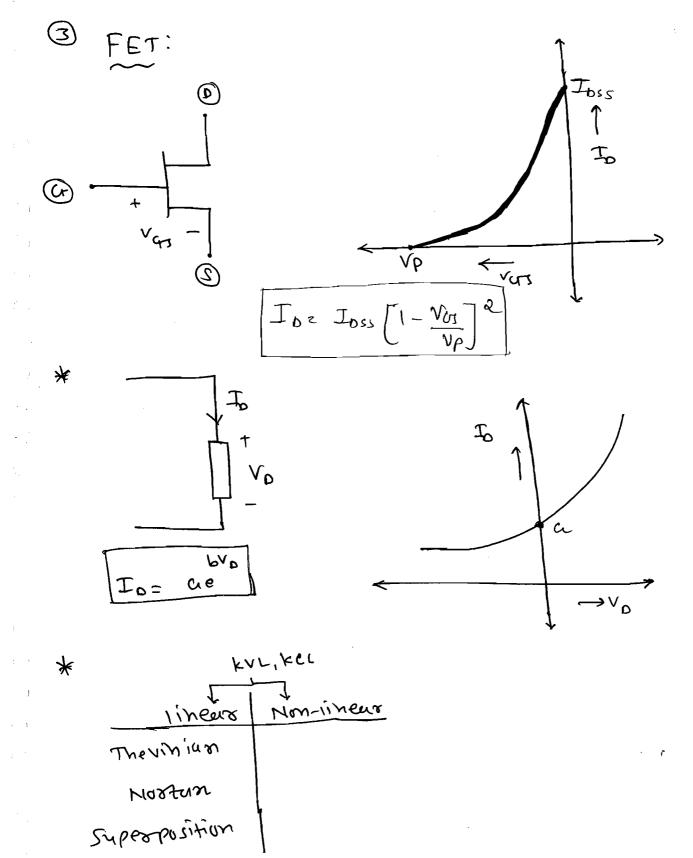
() ()

0

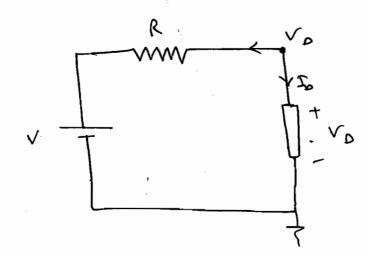


1 = 25mv = 15/3 A. 1vin=0.68 Vo = - 100 × 10 [e 25×123] : Vo = - 6.5 V Small Signal Analysis: -> Amp is linear operation. -> Nonzineus devices are as follow: (1) Diode: VBE -Vbe/vt

 \bigcirc



* Dc Analysis:



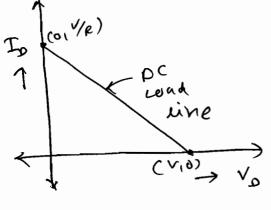
$$\frac{\text{kcL}}{R}, \quad \frac{V_{0}-V}{R} + \frac{T_{0}=0}{R} = 0$$

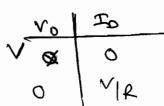
MOW, TO= Tore al

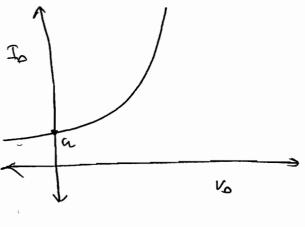
Solve By 1) force and erest.

2 Iteration [Numerical method].

* goupnical:







000

0

(...:

.

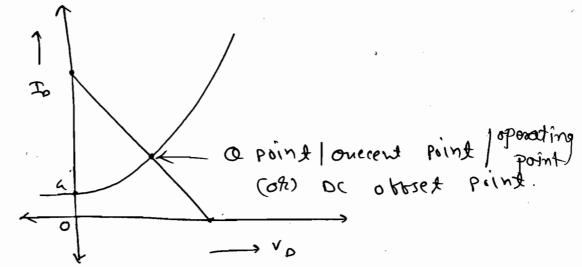
(<u>.</u>

C

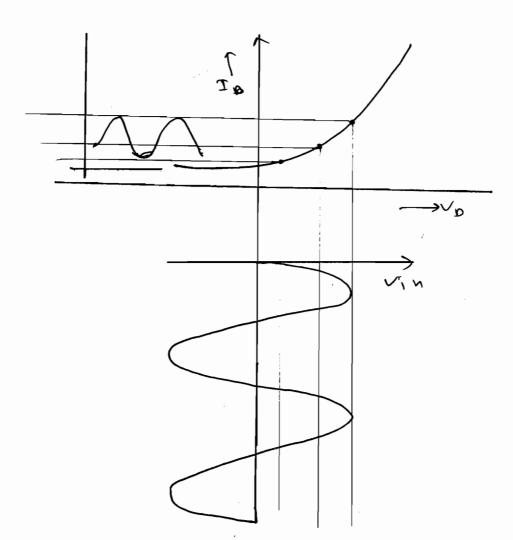
C

 \bigcirc

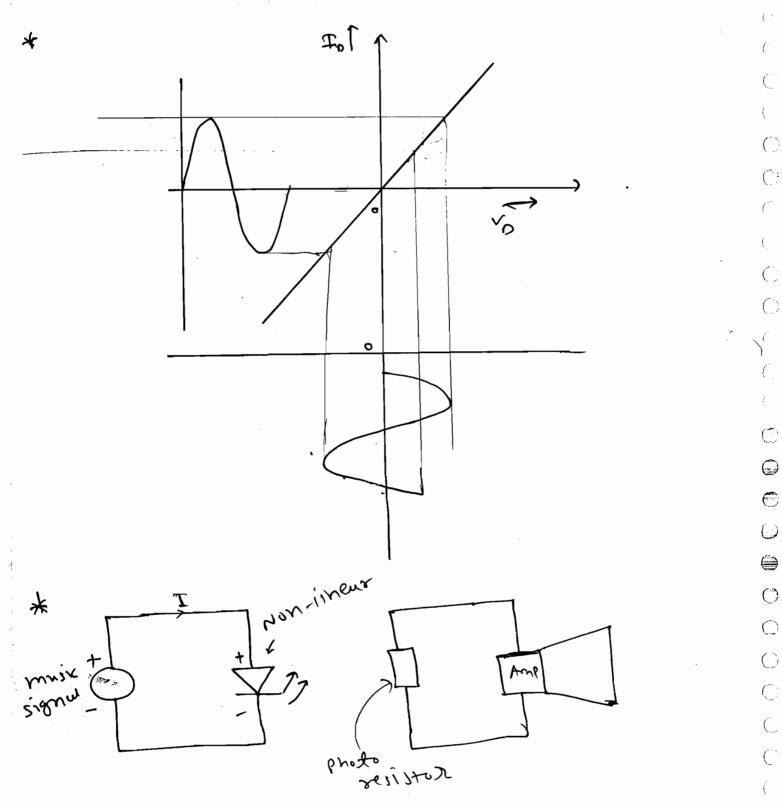
() (



×



The order to got same shape at output, the Characterstic must be likews. So, BIT, and how on active device has non-likeur device and they do not gave same shape as input is very large. So some soin is required.



- In order to get sume snape of input at output (Ampilied), Amp should follows the Same Shape or proto resistor and in order to do this proto resistor snowed bullow shape available at LED and LED should, follow Ment Shape

(÷

(

()

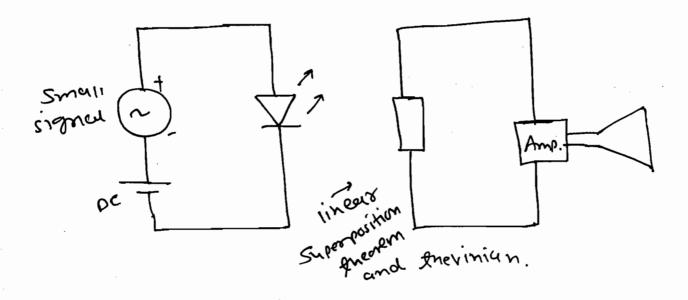
0

(

C

(....

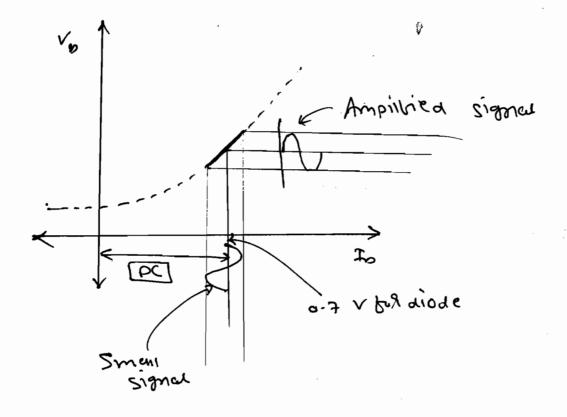
is the linear operation then 019 -> so , this is some as the input.



adding de biusing.

Thow, An devices has sume shape voltage

which is at input.



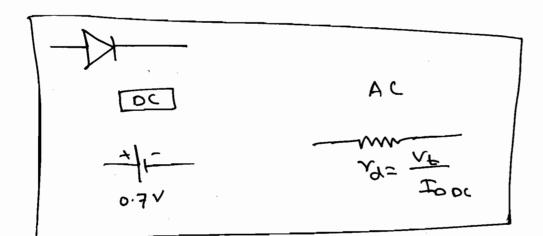
Small Signal Analysis: Add DC 2) keep the signal Small. non linear => linear. * Small signal Analysis of Diode: Vototer = vot vo. Jotoful = Jos + Jos. NOINF In nc = 3. e : Totated = Js. e . e -: Iotoral = Fo.or [1+ VDAR] =

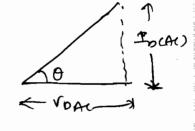
(َ)

: Took + For = For + For Ver

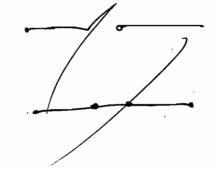
-> Diode Resistance,

$$(V_d) = \frac{V_{OK}}{Y_{OAC}} = \frac{V_b}{T_{OC}} = \frac{cosnto.}{cc}$$



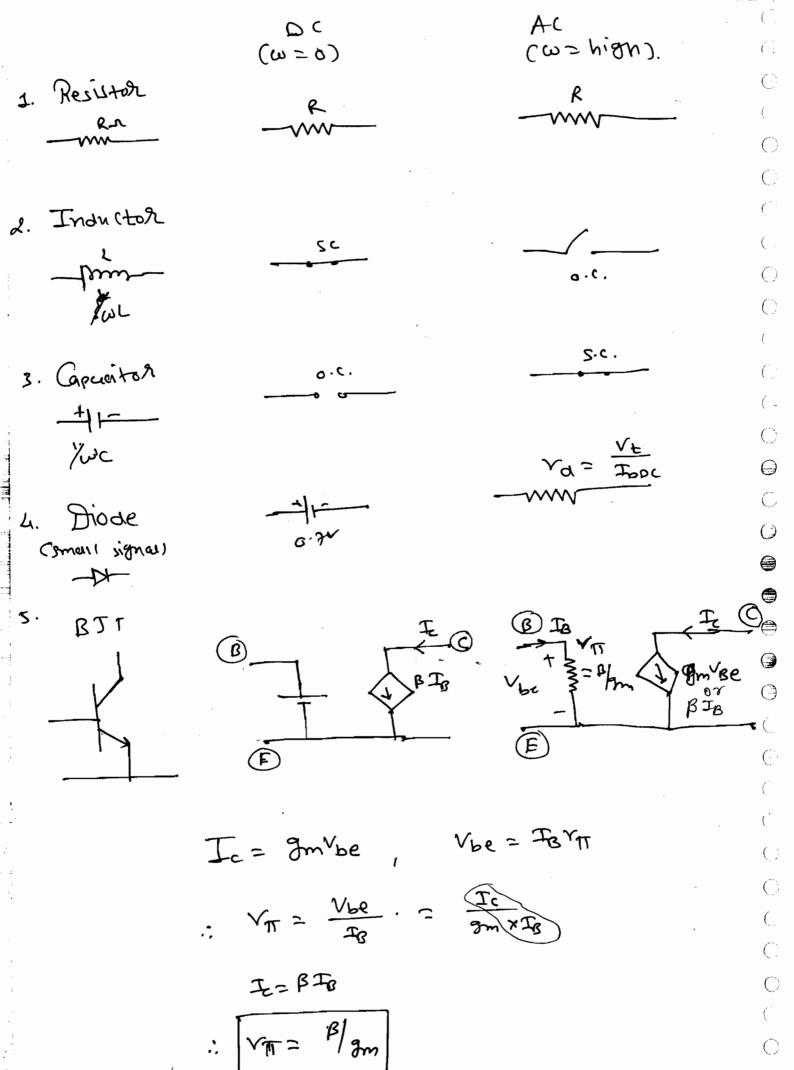


Diode work as a liheur Device.



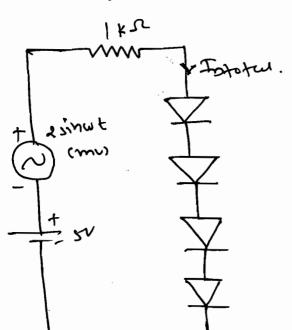
3. Capaciton

1



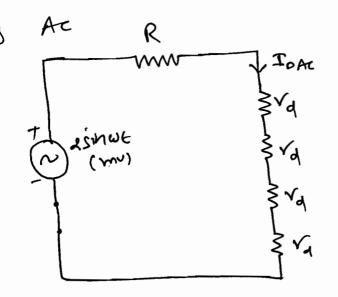
(

& Find the total Diode current it Vt = ASMV and forward drop Vo= 0-7 volt.



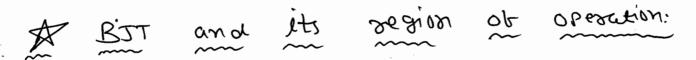
MOLLE;

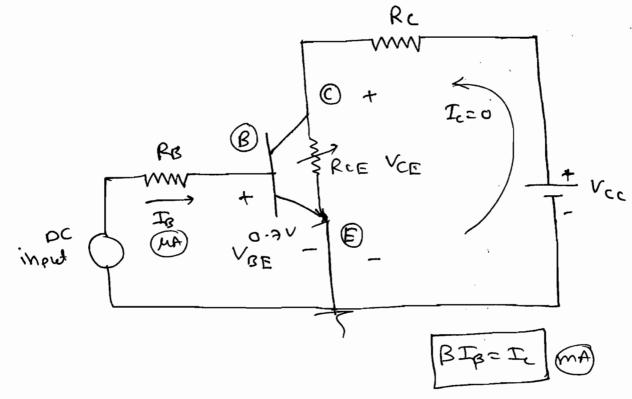
- (i) Diode is 2 terminal nomineur passive device.
- (ii) BJT is 3 terminal possisses | active device.



Topes 1-913 simut MA.

Foot Forc = 8.2 + 1. 313 sin Wt mA. Fototul =

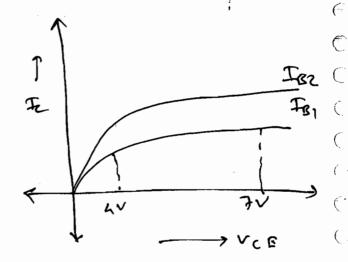




- Te is control by Is form input side.

$$: \quad \overline{T}_{e} = \frac{V_{cl}}{R_{e} + R_{e}^{2}} = 0 \quad \text{(ut other)}$$

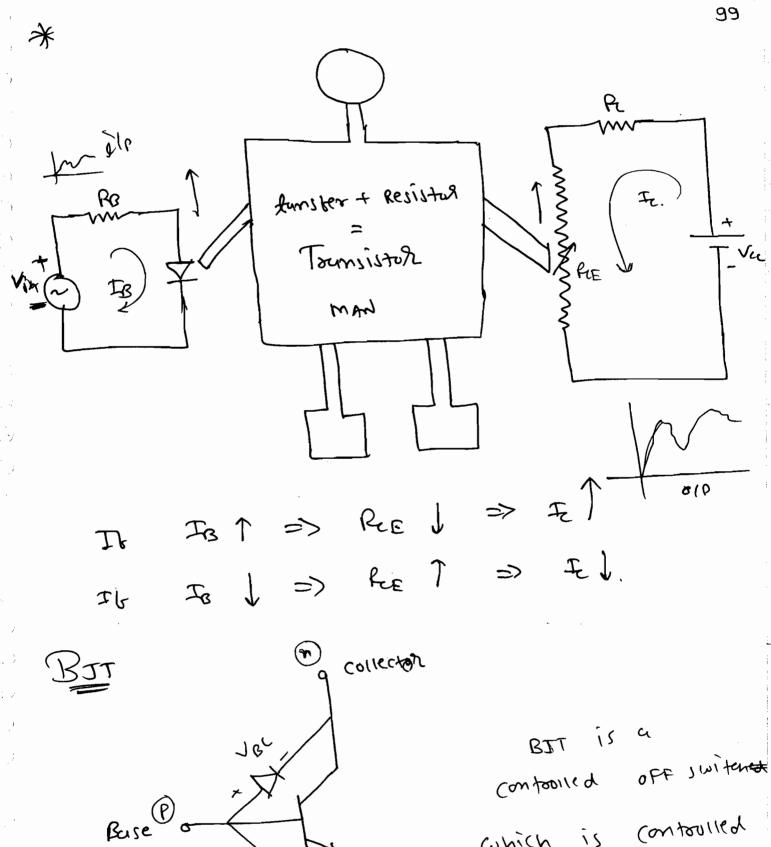
Vcc	Ic	VCE	Pre = VCE
5	Im	Ly	4K
6	12	5 V	2 K
7	1m	6v	e k
8	1m	2	714
Rczik			



(<u>;</u>;

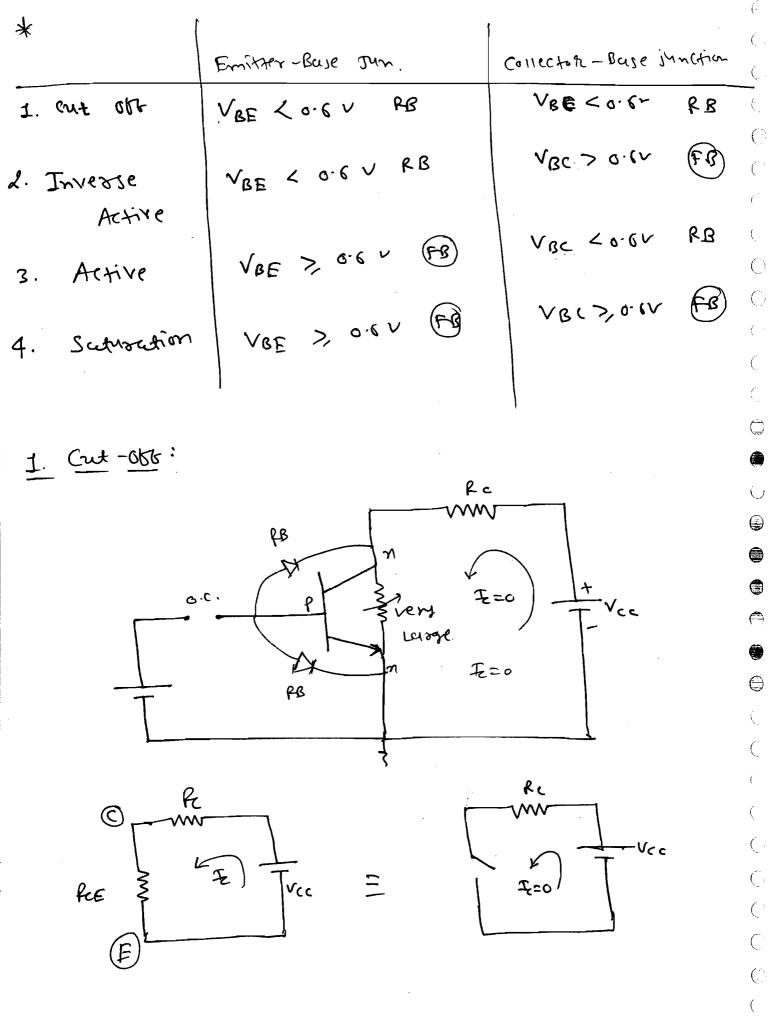
 \in

- JE is only change when IB of RB
 - -> SOI BIT IS CHOSENT GINTOUL CHOSENT SOURCE.

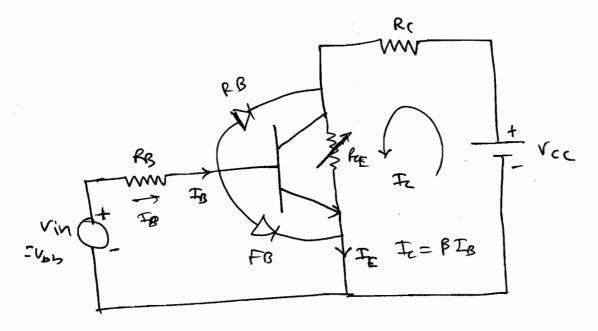


is contoulled which form input side. V 8E. 0.72

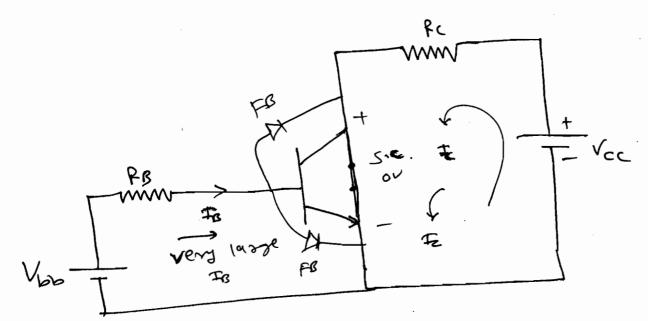
emitan



 $\left(\cdot \right)$



3. Satiscation:



| Ip | > | Felactive.

- : | IB | > | Tel: | Buctive |
- : Buctive > | Fe |.
- : Bfored < Bactive.

IB is very large

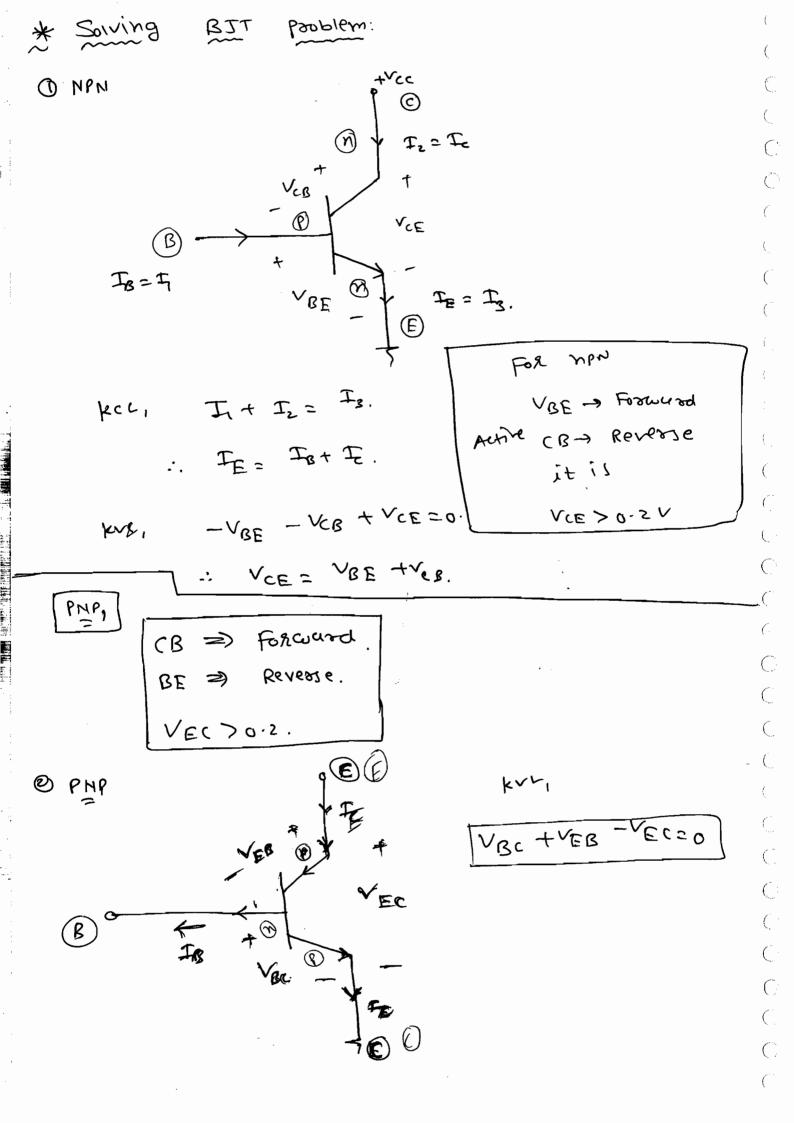
No effect on =.

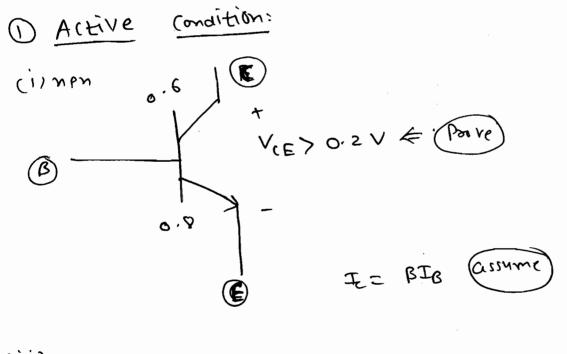
Resistance => BJT

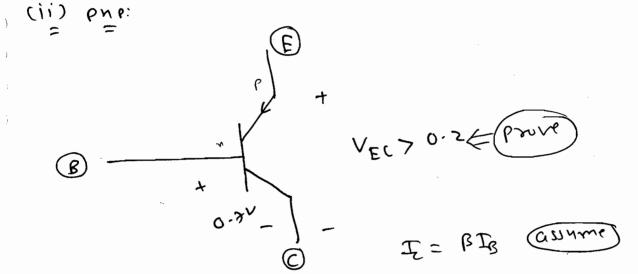
Cut other section

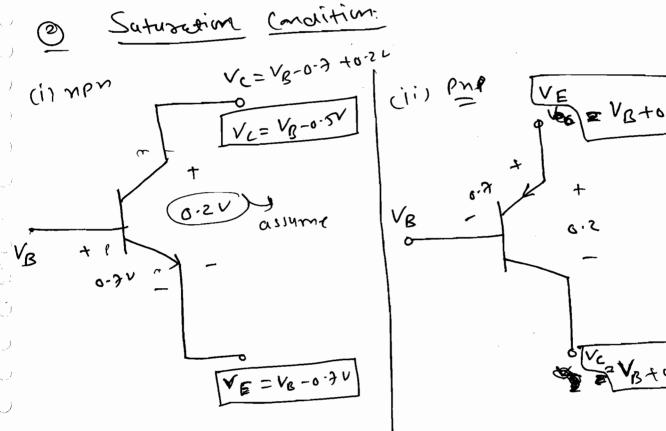
Active region for Ame.

Switches.









Bourced < Bushive Pour

Ex-1 Find An mode Voltage and Bounch

Result 100

Result VCE = VC-VE

VSE - TE

VSE - TE

SRE = 3.34

$$\therefore T_{E} = \frac{V_{E}}{P_{E}}$$

:.
$$T_{E} = \frac{3.3}{3.3 \text{ K}}$$

$$\therefore \frac{I_C}{F_E} = \frac{\beta}{\beta + 1}.$$

()

` (.·

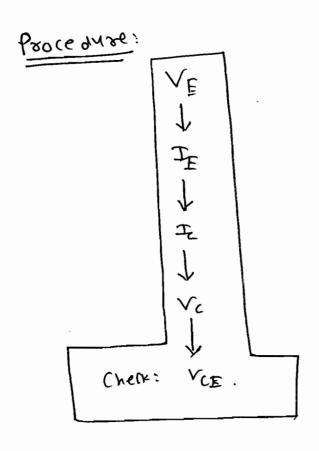
€.

€:

 \bigcirc

C

So, transistor is in active condition.



$$\frac{\rho_{\text{CS}}}{\sqrt{E}} = \frac{6 - 0.30}{\sqrt{1000}}$$

$$T_E = \frac{V_E}{R_E} = \frac{5.3}{4.3}.$$

$$:: T_c = \frac{\beta}{\beta + 1} T_E$$

()

() ()

0

 \bigcirc

 \bigcirc

 \bigcirc

 \overline{C}

(;

Ç.

(,,

(.

()

(

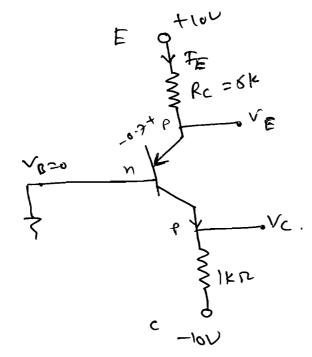
Mow, Let, VCE=0.2. and we will find Bromed.

$$I_{c} = \frac{10 - 5.5}{4.7}$$

So, trunsistan is in secturation region.

50, tounsisted is in outobt.

Ex 4 p



(

(:)

 \bigcirc

$$T_{E} = \frac{10 - 0.3}{5k}$$

:.
$$V_c = T_c R_c - 10V$$
.
 $V_c = (1.8h) - 10V$.
:. $V_c = -8 \cdot 18 \text{ m/H}$

BIL form * To make Sut the active to sut following two ways Com be applicable: (A) Doned Chactive 1 3 Vob1 →(i) I Show w and can be achive by incoensing value of Re: Re >> Large. 1.3K (11) By incremina Vbb Is Can be incoensea which in than reance the Borred.

 \bigcirc

0

0

0

Ex-4 Carculate the An node Voltages and

bounch Current &=100 and it is in suturation.

\$ \$

The variable of
$$V_E = 0.2V$$
 $V_E = V_B + 0.7$
 $V_C = V_C + 0.5$
 $V_C = V_C + 0.5$
 $V_C = V_C + 0.5$

$$I_{E} = I_{B} + I_{C}$$

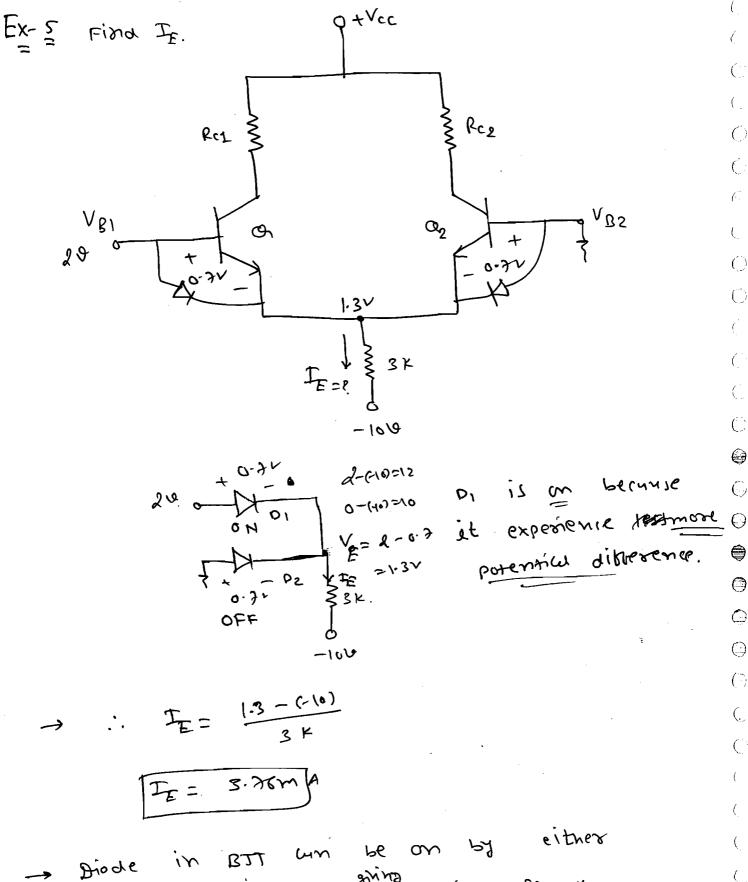
$$I_{E} = \frac{V_{B}}{I_{O}K} + \frac{V_{C} + S^{V}}{I_{O}K}$$

$$\frac{10(5 - V_{B} - 0.7)}{2} = \frac{V_{B} + V_{B} + 5 + 5 - 5}{2}$$

$$|2 \vee 8| = 37.5$$

$$|V_{R} = 3.125 \vee$$

So, it is in sut-

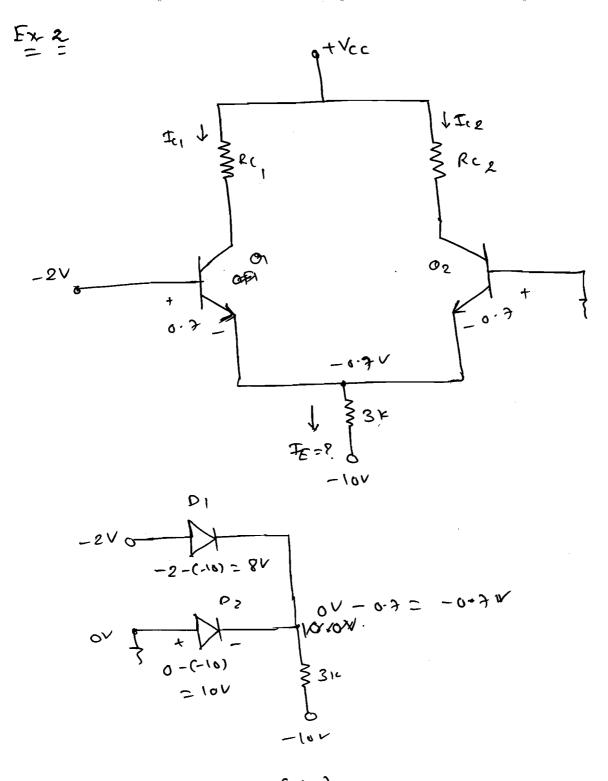


0

0

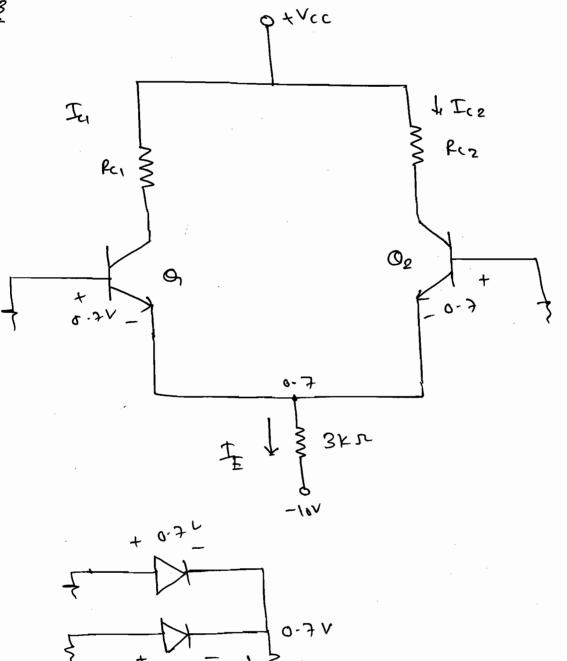
(E)

ghino on + negative . BIGG MZ divides



$$I_{E} = \frac{-0.7 - (-10)}{3k}$$

$$I_{E} = 3.1 \text{mA}.$$



(=)

 \bigcirc

€

 \bigcirc

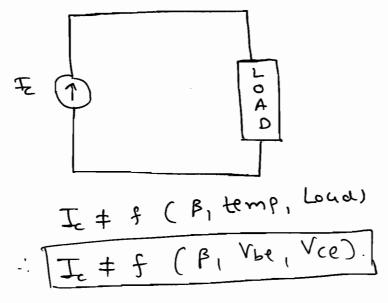
(::

$$T_{E} = \frac{0.7 - (-10)}{3k} = \frac{10.7}{3k} = 3.567 \text{ mA}$$

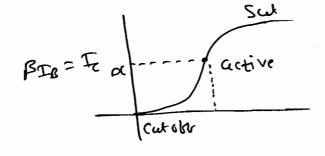
Biasing a BJT:

The Purpose of biasing is to switch on the BJT to Gork in active region such that the De collector current remain Constant independent of B1

Temp. and load variations.



1 B (with FE).



ib β Change the I= βIB Changes.

2) Temperature:

If temp. Chunges => VBE Changes.

Anis will Change Is and sum in Change

Ane I.

J Loud Vurications:

O vcc

ImA | K to SK

Vce

In order to sid this problem we should

make anstant current source.

•

 \odot

()

()

 \bigcirc

0

VBE = Const.

Fb > Comit.

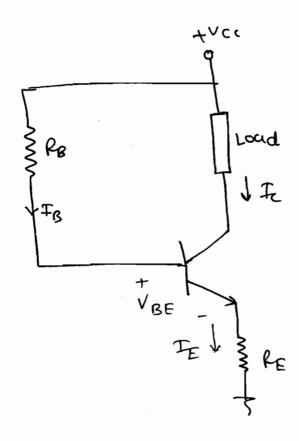
: Ig = Comst.

:. Fr = B Fo = B [Vu-VBE].

-> B Change: from so to 250 to 1 the different specimeny of the given Amnsistur type. any cxt which depend of a porticular value of Bis a bad (kt.

with PE without PE $I_c = \beta I_B$. $I_c = K = const$ $I_c = K = const$ $I_c = K = const$ Ic= BFB FB= K = const.

I= BIB



()

();

 \mathcal{L}^{2}

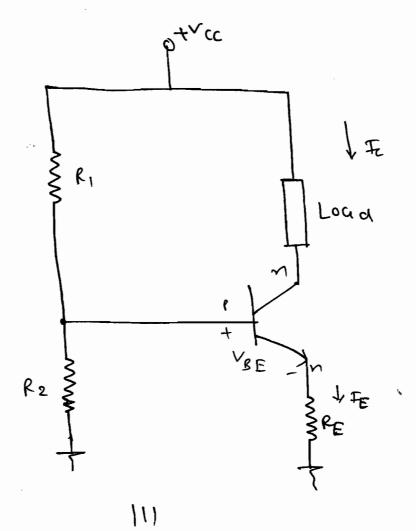
(

$$: V_{CC} - V_{BE} = \left(\frac{R_B + R_E}{R_{T1}}\right)^{T_E}.$$

Voituge divides

Self bias (of)
Universal bias.

>>>



The venian Load

Pennavaren

Rth

Vth (†)

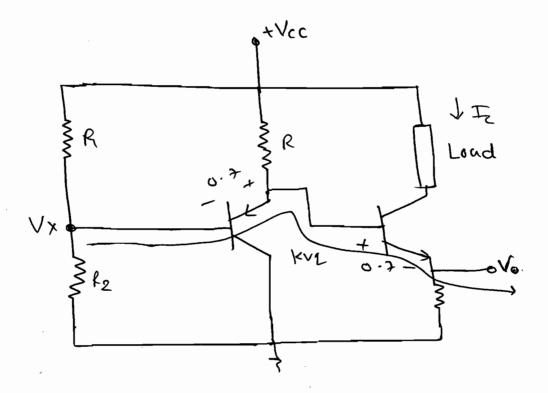
(ne gracking IR)

Ig = OA

Vth= Vcc F2
RITP2

 $Rtn = \frac{R_1 \cdot R_2}{R_1 + R_2} = R_1 \cdot 11R_2$

$$T_{E} = \frac{V_{en} - V_{BE}}{P_{E} + \frac{P_{B}}{P_{E} + 1}} = \frac{V_{en} - V_{BE}}{P_{E} + 1}$$



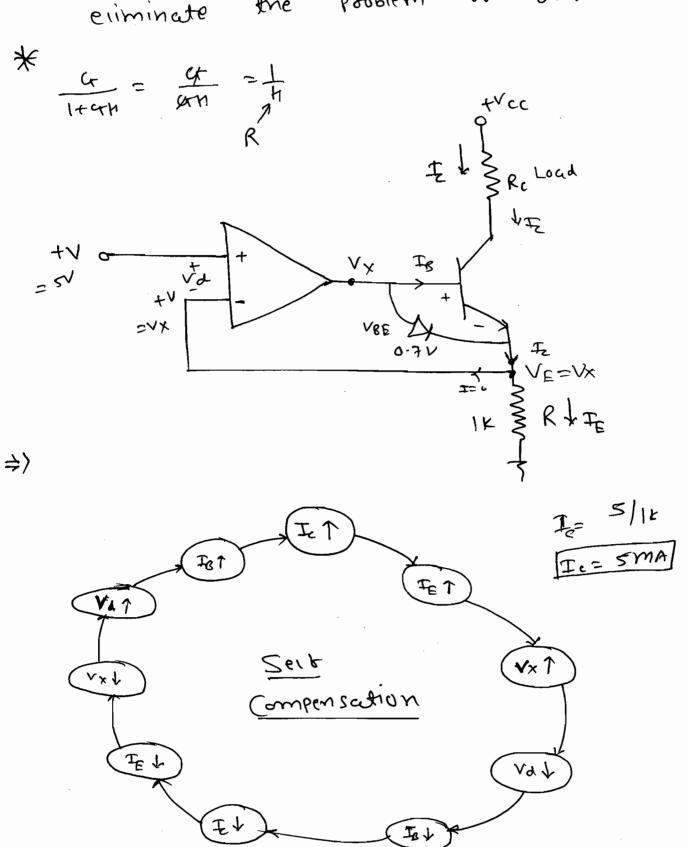
$$\rightarrow V_{X} = \frac{V_{CC} R_{2}}{R_{1} + R_{2}}$$

$$\therefore V_{X} + 0.7 - 0.7 - V_{0} = 0.$$

$$\therefore V_{x} = V_{0} = V_{E}$$

$$\therefore V_{E} = V_{0} = \frac{V_{cc} R_{2}}{R_{1} + R_{2}}$$

NoTE: Designing a current source with op-Amp in -ve feedback will totally eliminate the problem of drift.



()

()

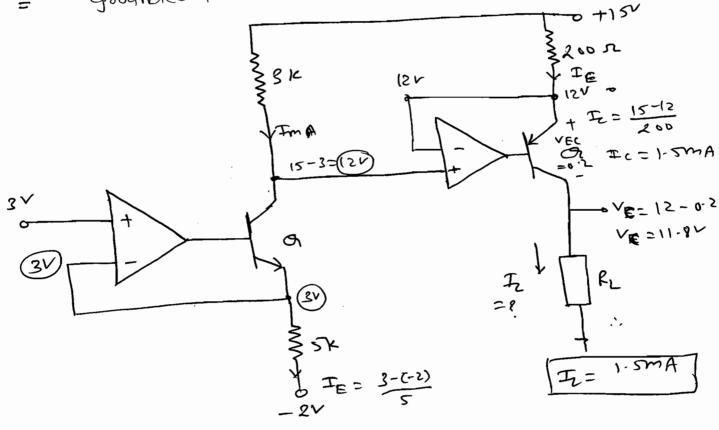
0

():

(,)

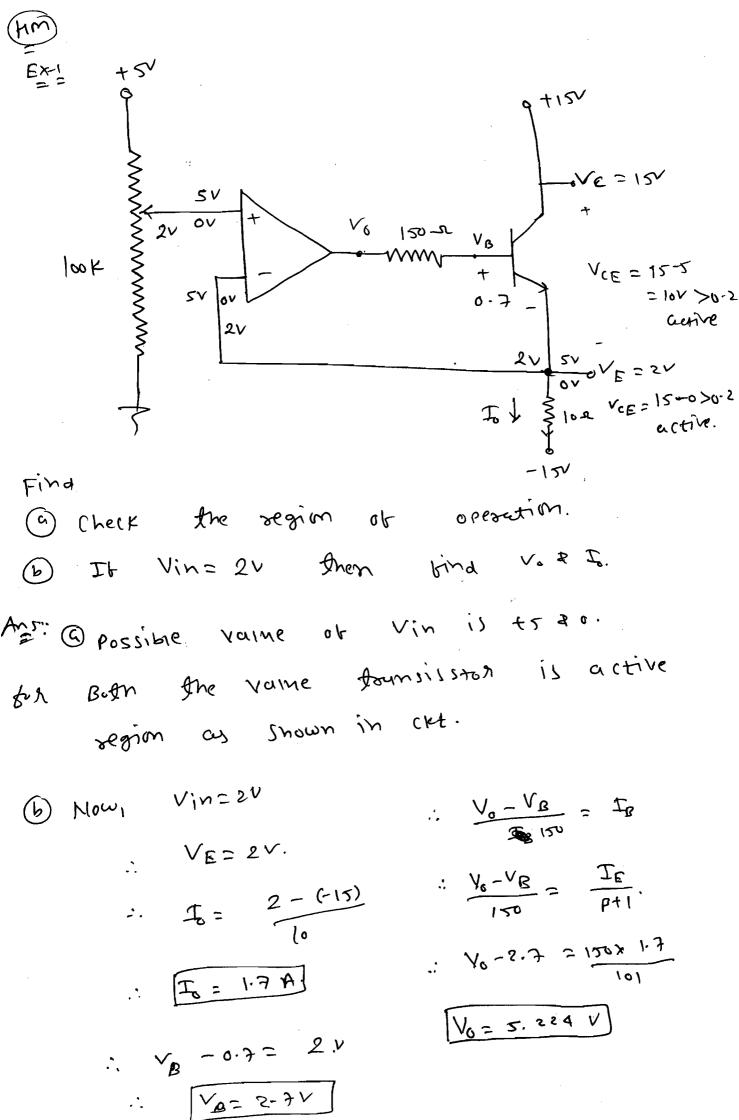
Temp. Changes but are pasameters Stuble because of -ve feed back mechanism which is provided by som-investing OP-Amp.

Ex-1 grounded load.



-> find the minimum value of R for the BJT to be in Sat. with VECZOZ.

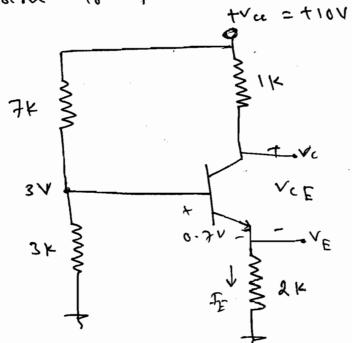
$$V_{C} = 12 - 0.2 = 11.8 V$$
.



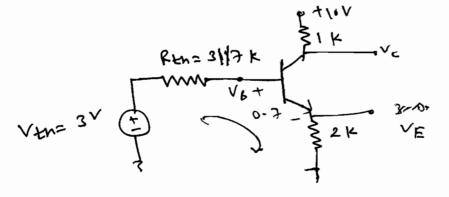
load	√cE ⁵	VCE;	Ic
IK	0.8	7·2 V	[mA
2 k	8.0	6.5 V	ImA
3 K	0.8	5.2 V	1mA
uk	0.8	4.2 0	1mA
5 K	0.8	3-2 V	1 mA

Ex-1 Caranate em node voitages and Bounch

Current it B=100.



Ans:



$$T_{E} = \frac{\sqrt{m - \sqrt{pE}}}{R_{E} + \frac{RM}{p+1}}$$

$$T_{E} = \frac{3 - 6.7}{2 + \frac{2.1}{101}}$$

(

 $\begin{pmatrix} 0 \\ 0 \\ 0 \end{pmatrix}$

 Θ

0

()

(,

(

()

(

(;

$$I_{E} = \frac{2.3}{2.02}$$

:
$$I_c = \frac{\beta}{\beta + 1} \times I_E$$
.

:
$$I_{c} = \frac{100}{101} \times 1.14 \text{ mA}$$

Ex-2 Calculate the all the Node Voltages and Branch currents.

()

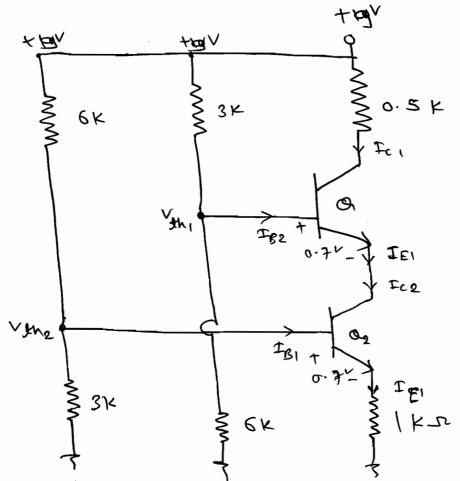
 \bigcirc

0

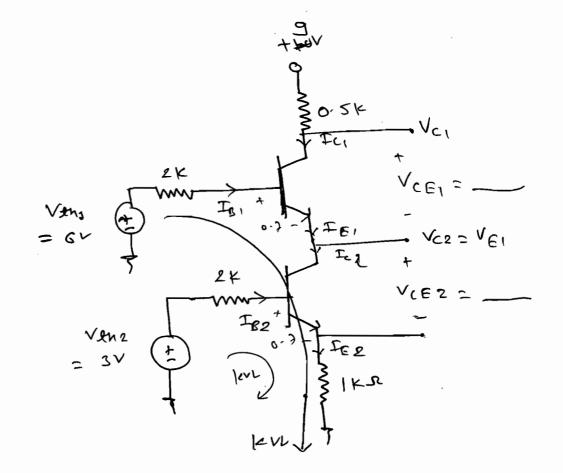
•

(

 \bigcirc



Ars:



PE + RATHI

129

RAM = 3x6

Rth, = 2 K.

Van = 3 x 8

= [IE2 = 2.255 mA]

Vgh, = 3 V.

: Ic2 = 15 x TE2.

: T2 = 100 x 8.255

:. Ic2 = 1.23 mA

 $T_{S2} = \frac{T_{E2}}{s+1}.$

= IB2 = 22.33 MA.

= Fc2.

: IEI = 2.23 mA.

.. Ic1 = B x Ic1

:. $T_{c_1} = \frac{100}{101} \times 9.23$

: Ic1= 2.21, mA.

: IBI = IEI 2 IBI = 22.08 MA

.: VER= FRX RE :. V = 2.255 X 1 ·. VE2 = 2.255V :. Vc1= 9- Ic1 Rc1 : vc1= 3- (5.51 x 0.2) · Vc(= 7.895V) Vtn1 - IBIRth, - 0.7 - VCE2 - IE2 PE2=0. .: VCEZ = 6- (0.02208 X2) -0-7 (2.255 X () & : [VCE2 = 3 V] # VOID VAM. - VOI = IB, : VCE 5 = V(5 - NES : VBI = Vth, - IB, Rth, .: Vc2 = 3 + 2.555 : VB1= 6- (0.02208 .. C2= 5.255V * VB1= 8.9528V * .. VEI = VC2 = · [NE1= 2.522 N] * VBZ = Vthz - IBZ Pene. 2. VBZ = 2. 955 V & -. VCE(= Ve(- VE(: , NCE1= 4.832 - 2-522 ·. VLE1 = 2.64 V.

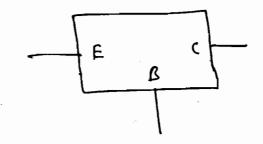
•

 \bigcirc

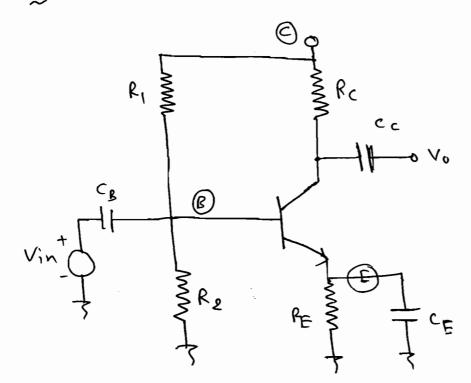
Con figuration

of BJT

- D Common
- Emitter
- 2) (ommon
- Buse
- 2) (common
- Collector



1) Common Emitter.



Zin= 1 ks

5 = 20 km

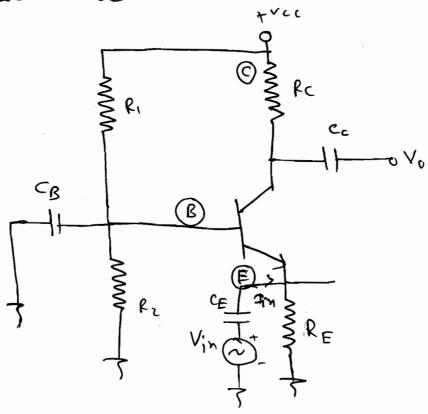
Au = -200

AI = -100

Ap = AYAI

Very high power gain,

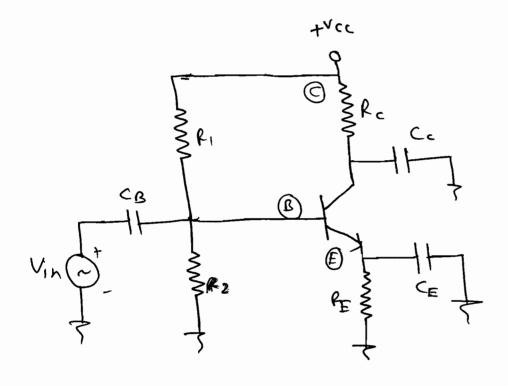
2) Common Base:



$$Zin = \frac{Vin}{Rin} = 30 \text{ s. =) CC}$$

C

(3) Common Collector:



$$Cc \rightarrow Vc \vee S$$

Av = 1 - voltage Buffer

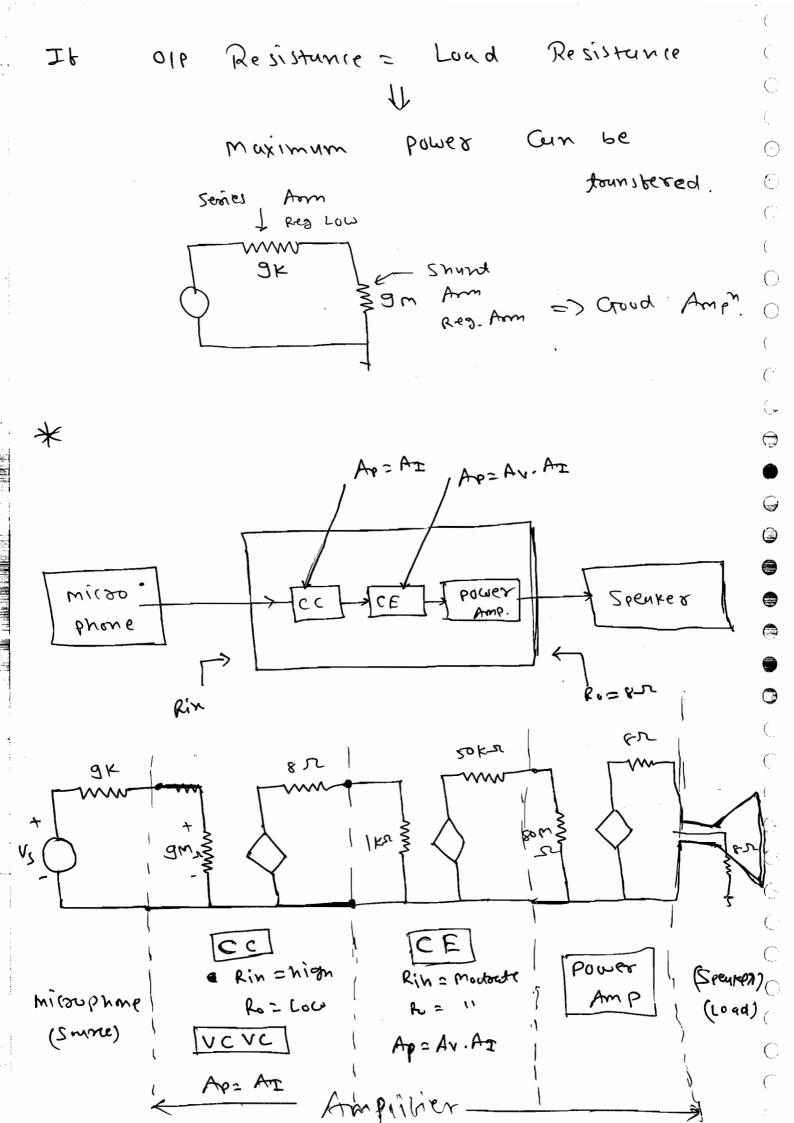
AI = 100.

= Ap= Ay, The

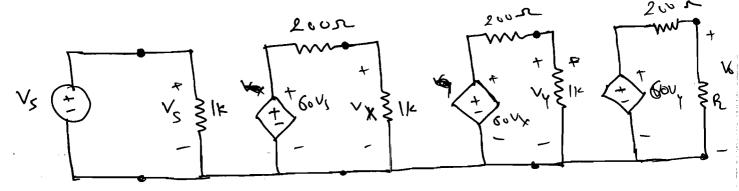
. Ap = A=

* Input inpedence is bound took Impedence metering

* Output Resistance es tound tor Maximum power loungter.



Ex: (1) An Amp hay an input Resisted of 135 CATE | K-SZ , OIP Resiston = 20052. It and Imple open loop voltage gain Ao = 60. It 3 similar Studes cascaded with a load Resiston R= 2.2 k. Find the over all voltage gain.



$$A_{v} = \frac{\sqrt{6}}{\sqrt{2}} = \frac{\sqrt{6}}{\sqrt{7}} \times \frac{\sqrt{7}}{\sqrt{7}} \times \frac{\sqrt{7}}{\sqrt{3}}.$$

$$V_{x} = \frac{60V_{5} \times 1^{k}}{200k + 1k}$$
 : $V_{y} = \frac{60V_{x} \times 1000}{1200}$

$$\therefore V_{x} = 50.V_{s} \qquad \therefore \frac{V_{y}}{V_{x}} = 50.$$

$$\frac{\sqrt{x}}{\sqrt{s}} = 50.$$

$$\frac{\sqrt{x}}{\sqrt{s}} = 50.$$

$$\frac{\sqrt{x}}{\sqrt{s}} = \frac{60 \sqrt{x} \times 2200}{2400}$$

$$A_{V=} = 55 \times 50 \times 50$$

$$A_{V=} = 1.375 \times 10^{5}$$

Analysis of BIT: oman Signa @ +Vcc VCB= Vcc Re a+fz TO block DC Bipuss RE bicsing Monimeur =) lineur. It loud connected to Vcc it is carred Rc (mpied (kt. brouging roud and it is It loud is connected to ground then it is called Founded loud and called Direct coupled (kt.

*	Puzrose	06	Euch	cup ucitos
1	1001036			

- → (1) CB → top De biasing.
 - ② CE → TO block Be and allow Ar in Vo.
- 3 RA CE Bipuss CE.
- →(i) CE behaver as open circuit took

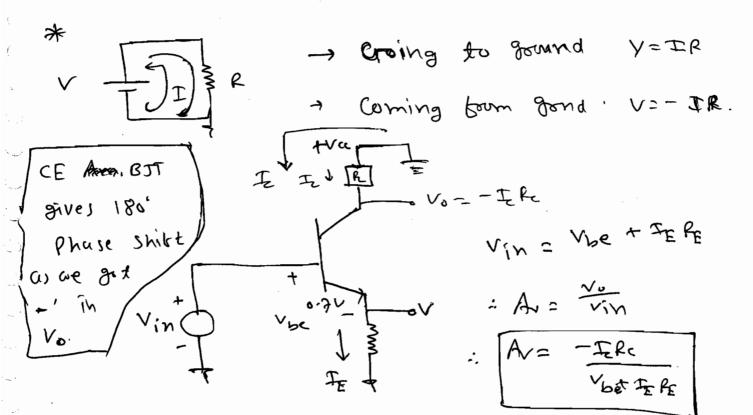
 De signal and it allows PE to

 Play its Role in establishing B

 independent De collectur (unsent. (Icoc)
 - (11) CE behaves as Short cirruit took

 AC signal eliminating the Crain

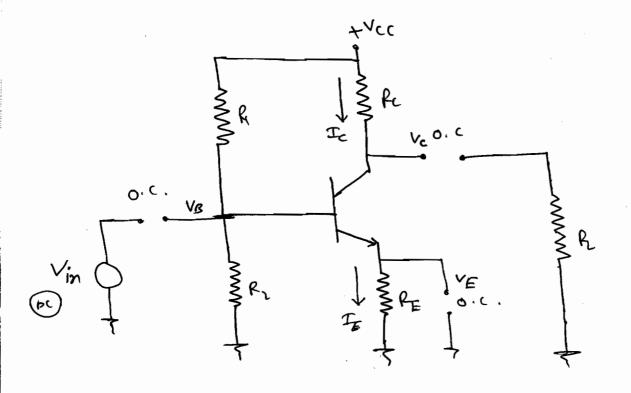
 Reducing emitter Resistor.



1) De picture:

-> Open cirruit the all capacital.

Atter that it is self bias.



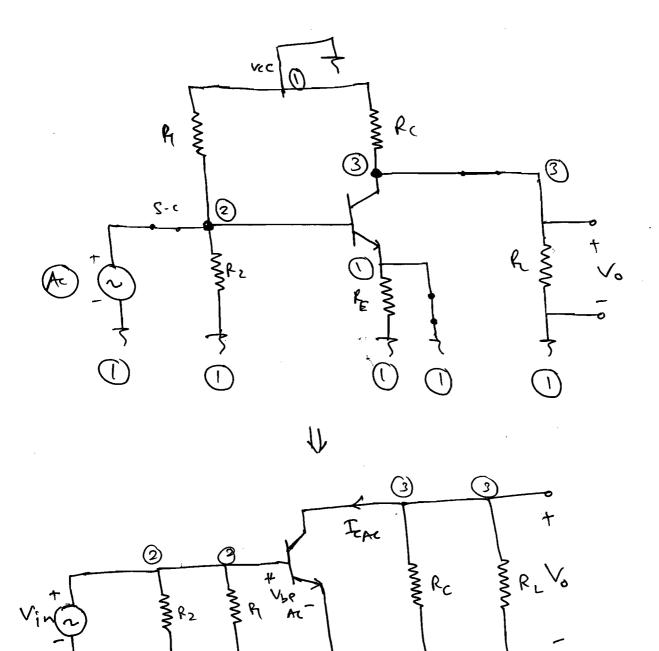
$$V_{CC} = V_{CC} - \frac{V_{CC}R_2}{R_1+R_2} - V_{BE}$$

$$R_{E} + \frac{R_111R_2}{\beta+1}$$

0

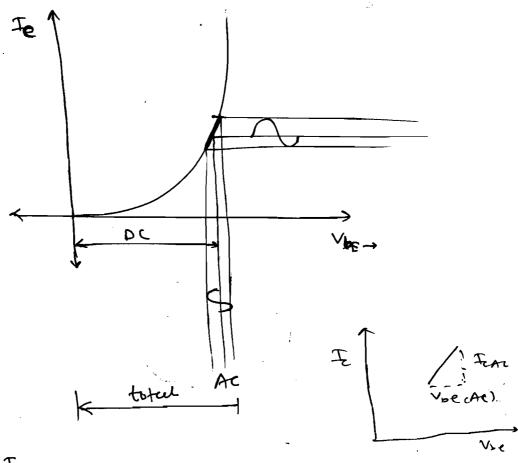
(_

-> Short cuts but the capaciton and DC Suppro



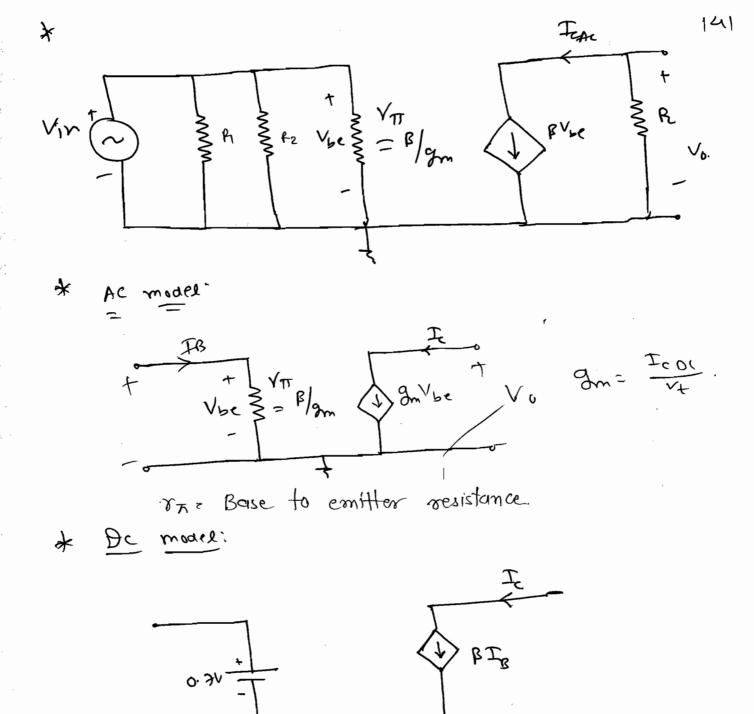
0

: Vin= Vbe (Ae).

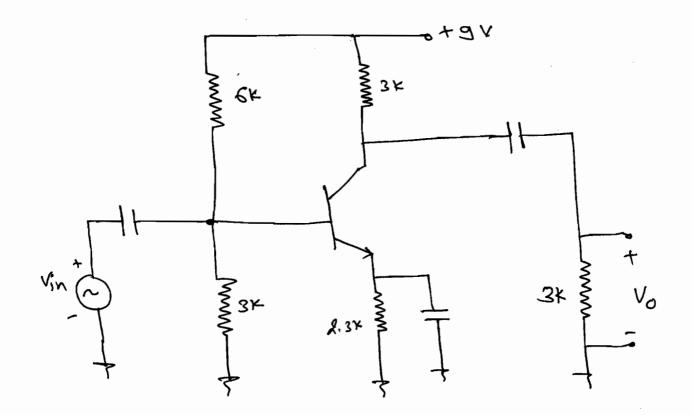


$$\therefore g_m = \frac{f_{c.oc}}{v_t}$$

()

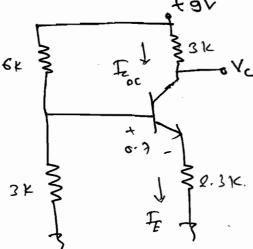


Ex-! Find the voltage gain Volvin it pis very large.



Wis:

o.c. the Capucitur



() ()

0 0

(:

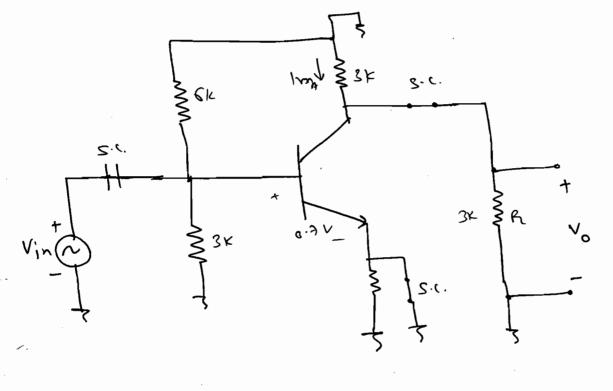
(:)

 \bigcirc

() ()

C

S.C. Capucitoh and Dc surres.



111

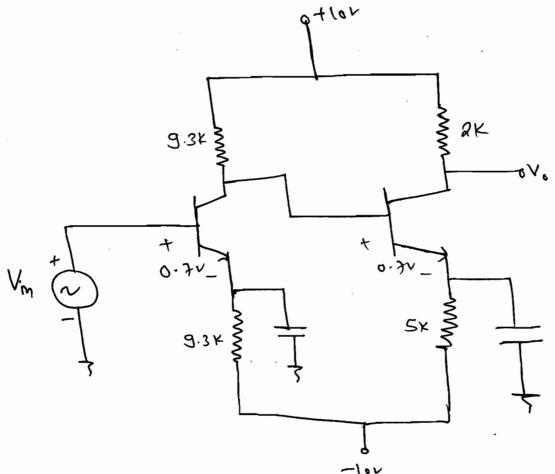
$$\frac{V_0}{V_{in}} = -0.4 [1.5] K$$

$$\frac{V_0}{V_{in}} = -\frac{1}{25} \times 1500 = 60$$

$$\frac{V_0}{V_{in}} = -60$$

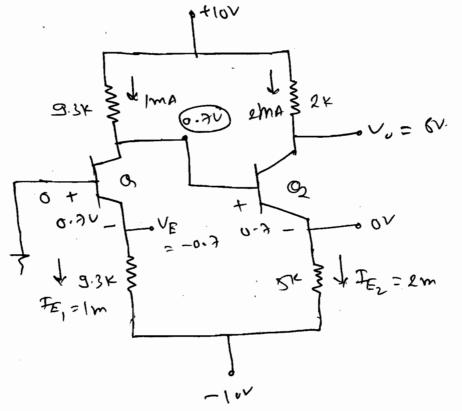
$$g_{m} = \frac{1}{25m} = 0.04$$

gm = From .



(,)

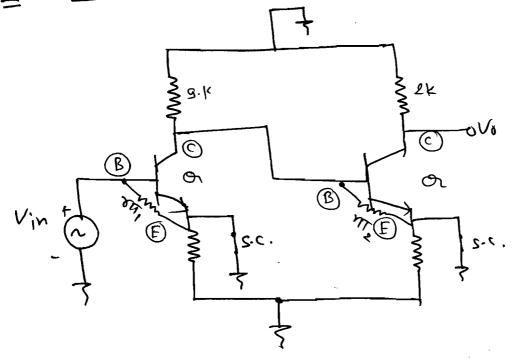
Ans: OBL picture.



$$\frac{1}{2} \cdot \frac{1}{V_{c_1}} = \frac{1}{10} \cdot \frac{1}{(9.3 \times 1)}.$$

$$V_{E2} = 0.7 - 0.7 = 0V.$$

1 Ac picture:



$$g_{m_1} = \frac{T_{c_{c_1}}}{v_t}$$

$$V_{m_1} = \frac{100}{\frac{1}{25}}$$

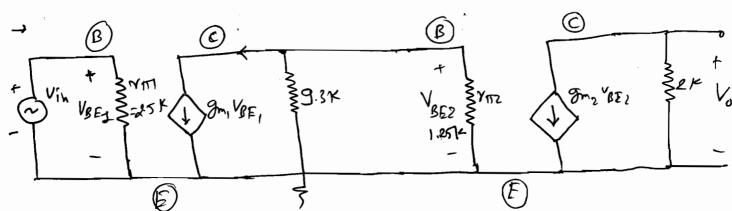
$$g_{m2} = \frac{f_{c}}{V_{t}}$$

$$= \frac{2m}{25m}$$

$$\therefore \left[\frac{2}{2\pi z} = \frac{2}{25} \right].$$

Mow





.

(· (·

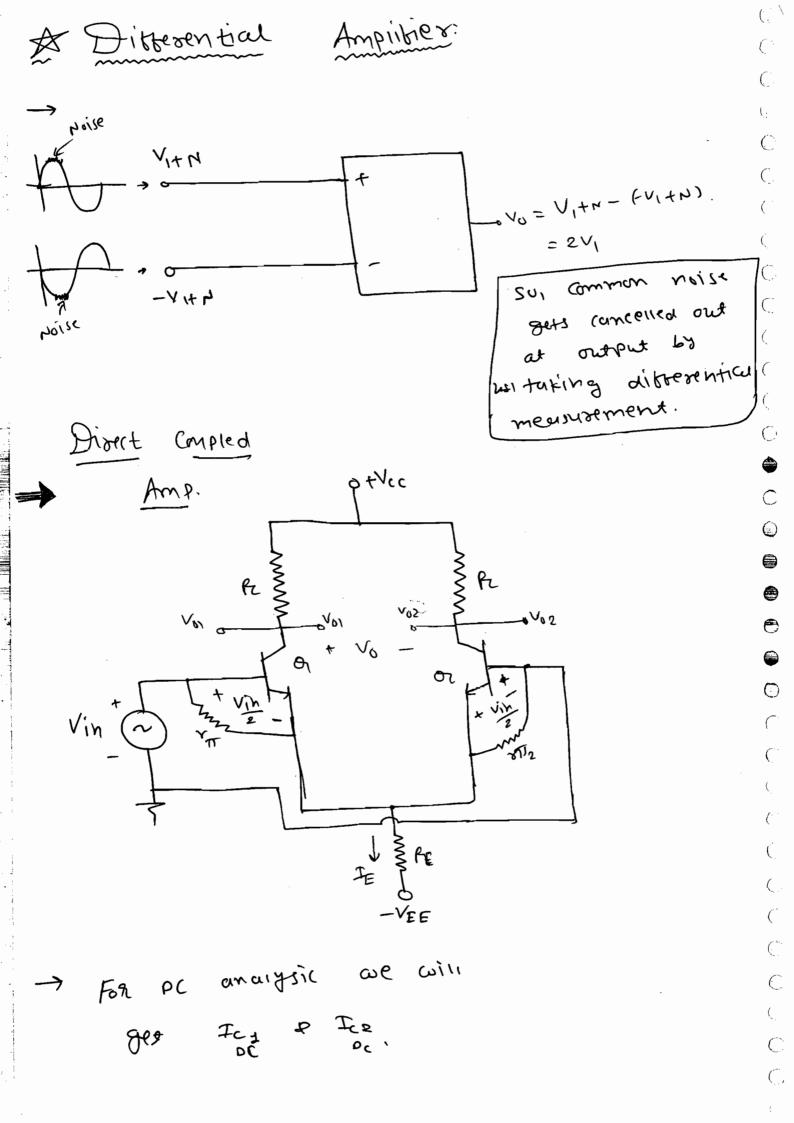
(.(

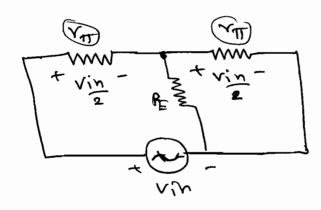
()()

(, (,

=
$$\frac{\Lambda^{1}\nu}{\Lambda^{0}} = \frac{\Lambda^{0E5}}{\Lambda^{0}} \times \frac{\Lambda^{0E1}}{\Lambda^{0E5}}$$

$$\frac{V_{0}}{V_{in}} = -g_{m2}(2k) \times -g_{m1}(1.25k) = -g_{m2}(2k) \times -g_{m1}(1.25k) = -g_{m2}(2k) \times -g_{m1}(1.25k) = -g_{m2}(2k) =$$





-> Here, RE >> out (:) PE is in Mr. and
You is in Kas.

So. PEll YTT & YTT

So, RE is Shunted by MT (dynamic

resistance) as RE>>YTT.

NOW, Voi = - Ic, Rc.

Ic = -gm

· Vo1 = - gm R(. (VBE1)

: Voi = - gmPr (Vin)

C: VBE(= Vin See Gid.).

Similiand

Voz = -9mRc (-Vin) (: VBEz = -Vin).

: Vo= Vo1- Vo3

= -9mR((Vin - (- Vin)).

: Vo= - 9mRc Vin

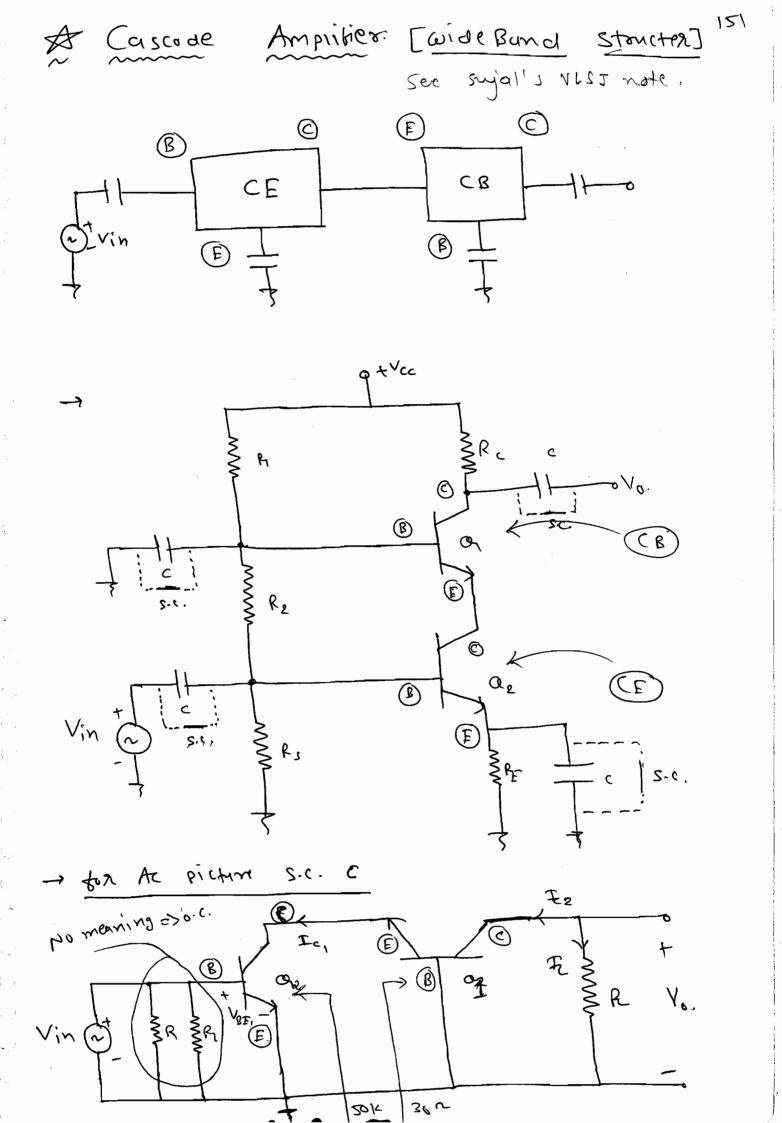
So, $A_{v} = \frac{V_0}{V_{in}} = -\frac{2}{3}mR_c. = A_0 + \frac{2}{3}mR_c$

- * CE amplifier Surrery from all Common problem. (Noise, drift etc).
- -> Dible. Amplifier eliminates such kinas of au Inese problem.
- -> (E ampribles poactically never used.

NOTE:

- Differential Ampilier is a Busic Building

 (Block of Analog Ic designe.
- Need for voitage divider and Comprising Compacitor to bias the BIT is eliminated in differential amplifier with -ve supply.
- The need took the Bypusi Capuciton is eliminated in a differential amplifier with two Symmetrical structure (off) with a two Symmetrical circuit.
- -> Of p capacitor is eliminated By differential measurement.
 - -> The input capacitoh is eliminated by regutive syppit.
- -> Capacitoh has to be eliminated because it takes more space in circuites and the soil of this problem is differential amplifier.



Vin= VBECAC).

Vo = Irc

$$A_{Y} = \frac{V_{o}}{V_{iN}} = \frac{-\frac{T_{c(AC)} \cdot R_{c}}{V_{BE(AC)}}$$

$$\rightarrow$$
 Bw = $\frac{1}{RC}$, time constant = RC.

Cea ? (miller effect)

R de (Croos) impedence mismateur.

(*

(.

 $(\hat{x}_{ij},\hat{x}_{ij})$

- → one aug to improve Bu is by giving
 -ve feedback but -ve feedback reduced the
 gein.
- -> But in Bir Gesecode Amprilier Bwis increased without Reducing gain.
- -> <u>Casecode</u>: Connection of © of CE to the ® of
- -> Cose Cade: : OIP OF one stuge is connected to the lip

* Advantages:

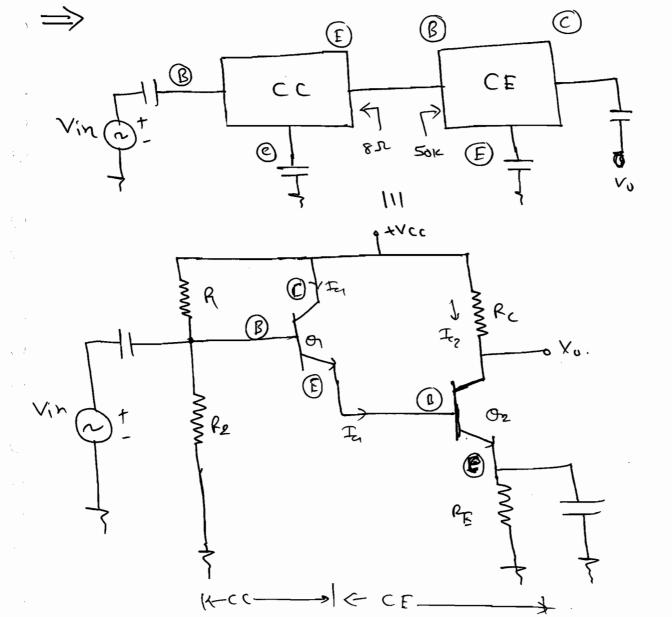
- wider BW.

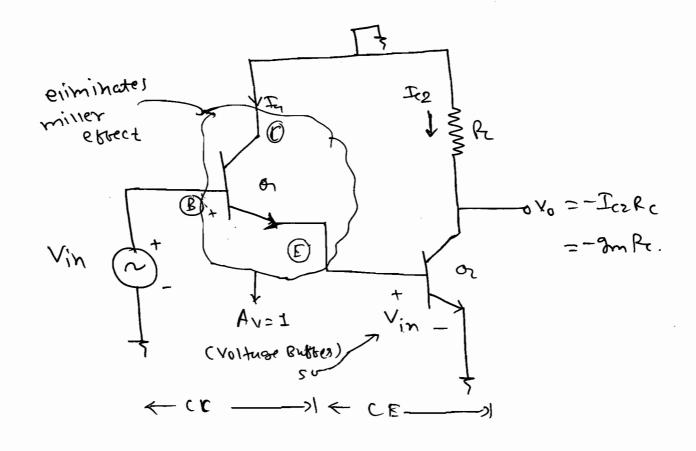
-> The oxercul tours conduction of Casecode Amp = the larger tours conduction of Common

Emitter amprifier.

-> Large Output Impedence.

E Wide Band Stanch re].





()

(

0

0

0

()

 \bigcirc

 \bigcirc

(

(

(-

(-

-> (noted Butter at old (Ar=1) (A)

Voltage Butter at ilp (Av=1) is put

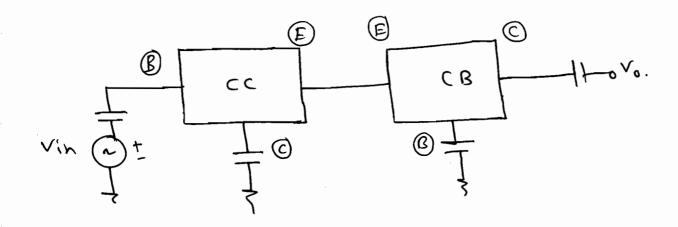
inorder to avoide miller's effect.

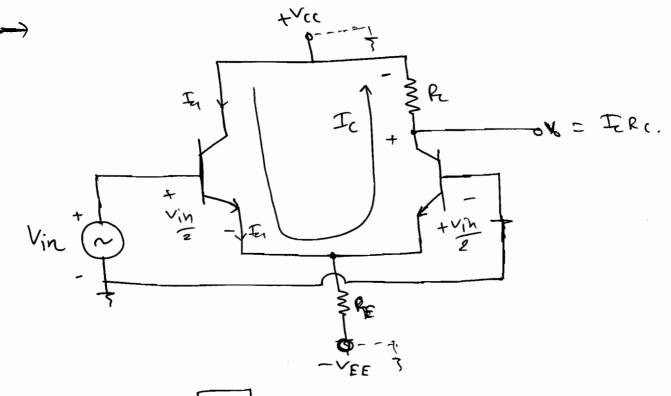
-> The Overall Lounsconductunce is Im

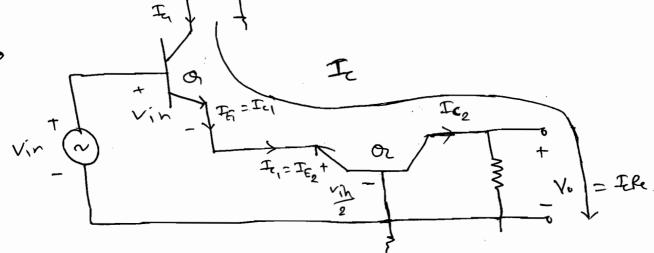
and voituge gain,

:. Av= - 9m Rc

* Common Collector with Common Buse:



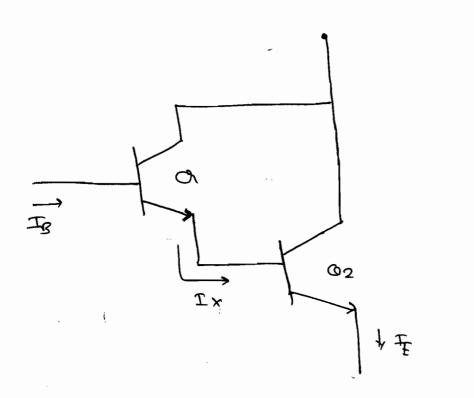




-> Vo= ERE

$$A_{V} = \frac{V_{o}}{V_{in}} = \frac{I_{c.R_{e}}}{V_{in}}$$

Derrigton Toursiston Paix:

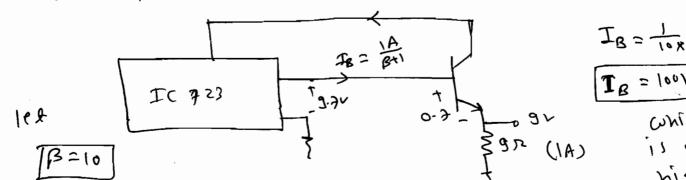


Ix = (B+1) Ig.

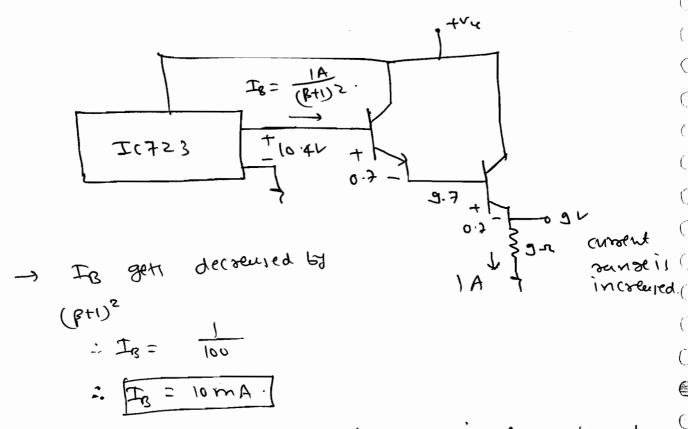
To dear with worst load, darligton pair used.

1et, 9-2 loud

Here, voltage at Ie all is, go and loud is connected which is gr. So, current browing throngh the ckt is IA which is too high top the IC723. becomse IC723 can handle maximum current upto loomA. and Ite gets byon. NOW, Put toursistor as shown in figure.



Darrington pair of Tounsiston. Now, use



do sind worthisop Eq warier MOW, IC $\omega \gamma$ founsistor.

0

 \odot

 \bigcirc

0

 $\left(\cdot \right)$

NOW, Inorder to produce gv across Inc is available gr PLoud 1 A chesent or daringator pair even it becomse is 10mA. current trowing through FC The seguised current gain (loma to IA) is provided by dariington pair.

 E_{x-1} (allulate node Voltage and Branch 9 movent.

 $|a_0 \times |a_0 \times$

: VIn- IBIRIN - VBE - VBE - FEZ REZ = 0.

. Now,
$$\overline{T}_{E2} = \frac{\overline{T}_{B2}}{(\beta t_1)}$$
.

But $\overline{T}_{B2} = \frac{\overline{T}_{B1}}{(\beta t_1)}$.

$$T_{E_2} = \frac{2.5 - 1.4}{3000 + \frac{50000}{(76)^2}}$$

$$: \quad \pm 2 = \frac{75}{76} \times 0.366$$

$$V_{B1} = V_{AN} - V_{B1} = V_{AN} = V$$

$$V_{B1} = 2.5 - 0.003167$$

(=)

0

 \bigcirc

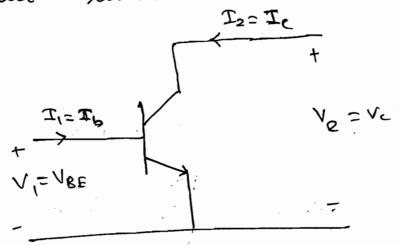
(

(__;

()

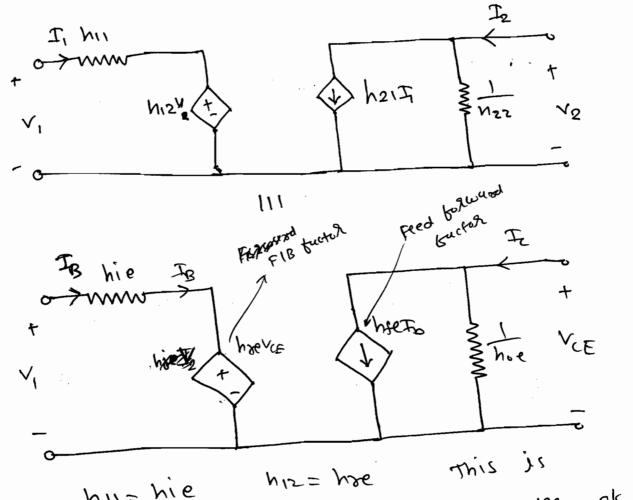
B

A Hybrid Model:



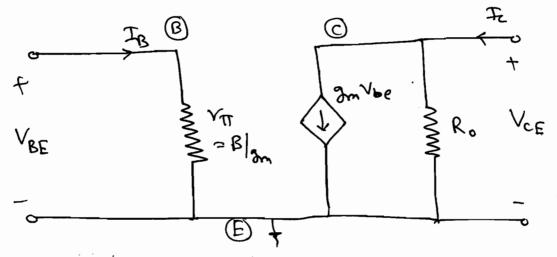
-> V1= h11 I1 + h12 V2 (KVL, Shevenian)

I== h21 I1 + h22 V2. (KCL, Norton).

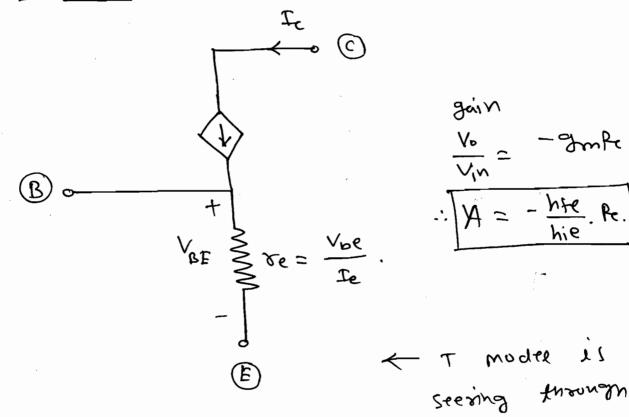


Where, his hie hiz=hre This is, $h_{21} = hfe \quad h_{22} = hoe. \quad \frac{\text{H moder}}{\text{Trunsistor}} \text{ of}$

12 \rightarrow as the hire = 10^{-12} and he = 100are an negrate hire and the ckt will be + ¥hie VBE Now, hoe = Por True = 1 Slope ound effect Roezick 40 x4 AB 6820. VCBhoe = 0. eany Voltuge H-model is as below: tina



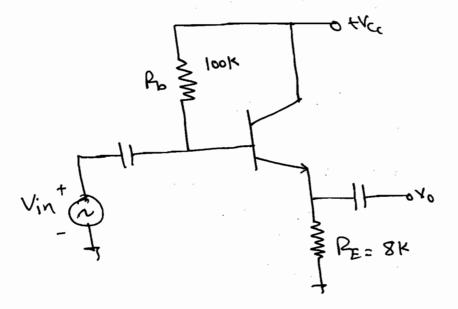
T- Modes:



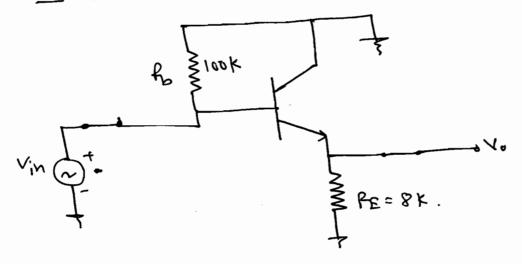
re= Vbe = 1 to find operting point.

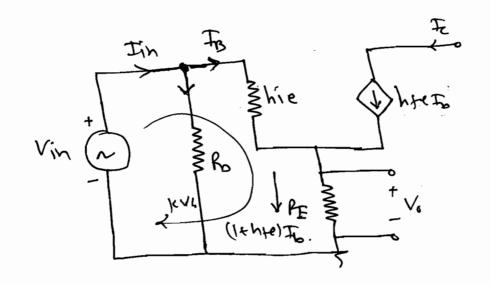
emitter.

For emitter Follower Circuit sives carrurate input impedence, of p impedence and voltage gain. hie=1k, hte=100.



bictuse:





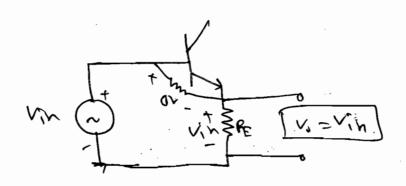
£.1

we can negate hie at the begining and

 (\bar{z})

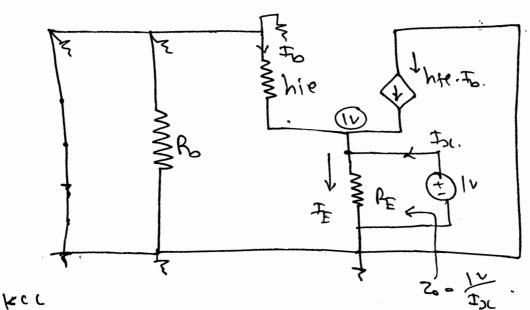
(

(-)



$$Tin = T_0 + \frac{Vin}{rh}.$$

-> Now, finding of impedence.



Fo + Ix + Iz IE.

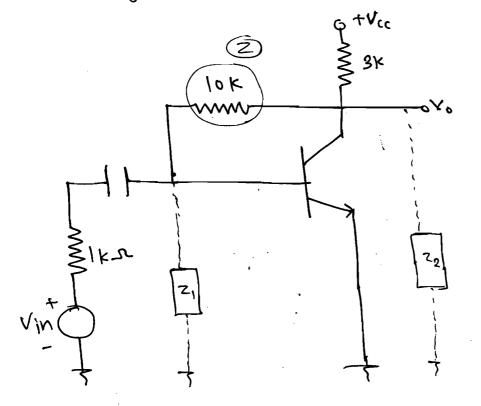
$$\frac{o-1v}{hie} + I_X + hte. \left(\frac{o-1}{hie}\right) = (1) \frac{1}{R_E}$$

... Zu= PEII hie ...

GATE, IFS

Ex-2 Using the milless throsem find the

Voltage gain Volvin it hie=1k, her=100.



Ans: * Miller's theorem:

$$J_1 = \frac{V_1 - V_2}{2},$$

$$J_1 = \frac{V_1 - 0}{2}.$$

$$\frac{V_1 - V_2}{2} = \frac{V_1 - 0}{2!}$$
 but $V_2 = AV_1$

(

(,

(.

(

(

$$\therefore \frac{V_1 - AV_1}{2} = \frac{V_1}{2}.$$

Similard,
$$I_1 = \frac{V_1 - V_2}{z_1} = \frac{0 - V_2}{z_2}$$

$$\frac{\frac{V_2}{A} - V_2}{\frac{7}{2}} = \frac{-\frac{V_2}{7}}{\frac{7}{2}}.$$

$$\frac{1}{2} = \frac{1}{2} = \frac{-\sqrt{x}}{2x}$$

$$=\frac{2}{1-\frac{1}{4}}$$

NOW, Ae picture,

$$Z_1 = \frac{10k}{1-A}$$

$$A = \frac{V_2}{V_1} = \frac{V_0}{V_1}$$

$$A = \frac{V_0}{V_1}$$

$$A = \frac{-190}{1000} \left[\frac{1}{\frac{1}{3000} + \frac{104A}{104A}} \right].$$

()

(*)

0

$$\frac{1}{3000} + \frac{10000 A}{A-1}$$

$$|aA| = \frac{1}{3000} + \frac{A-1}{10000A} = -1.$$

$$\therefore \frac{10A}{3} + \frac{A(A-1)}{1} = -1000.$$

$$(3A - 3 = -3600)$$

$$= A = -230.5$$

$$\frac{V_{in}-V_{i}}{2}=\frac{V_{1a}}{2}+\frac{V_{1}}{1k}.$$

:.
$$V_1 \left[\frac{1}{1000} + \frac{1}{43.2} + \frac{1}{1000} \right] = \frac{Vih}{1000}$$

$$\frac{V_0}{V_{in}} = \frac{V_0}{V_i} \cdot \frac{V_1}{V_{in}}$$

$$=(232) \times (2520)$$

$$A = -9.2$$

Now, By inspection are an do it easily.

Ų,

 \bigcirc

e

()

C.

C,

.

.

.